

Components and materials

Book C9

1984

Piezoelectric quartz devices

PIEZOELECTRIC QUARTZ DEVICES

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DATA HANDBOOK SYSTEM

Our Data Handbook System comprises more than 60 books with specifications on electronic components, subassemblies and materials. It is made up of four series of handbooks:

ELECTRON TUBES BLUE

SEMICONDUCTORS RED

INTEGRATED CIRCUITS PURPLE

COMPONENTS AND MATERIALS

GREEN

The contents of each series are listed on pages iv to viii.

The data handbooks contain all pertinent data available at the time of publication, and each is revised and reissued periodically.

When ratings or specifications differ from those published in the preceding edition they are indicated with arrows in the page margin. Where application information is given it is advisory and does not form part of the product specification.

Condensed data on the preferred products of Philips Electronic Components and Materials Division is given in our Preferred Type Range catalogue (issued annually).

Information on current Data Handbooks and on how to obtain a subscription for future issues is available from any of the Organizations listed on the back cover.

Product specialists are at your service and enquiries will be answered promptly.

February 1984

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ELECTRON TUBES (BLUE SERIES)

The blue series of data handbooks is comprised of the following parts:

- T1 Tubes for r.f. heating
- T2a Transmitting tubes for communications, glass types
- T2b Transmitting tubes for communications, ceramic types
- T3 Klystrons, travelling-wave tubes, microwave diodes
- ET3 Special Quality tubes, miscellaneous devices (will not be reprinted)
- T4 Magnetrons
- T5 Cathode-ray tubes
 Instrument tubes, monitor and display tubes, C.R. tubes for special applications
- T6 Geiger-Müller tubes
- T7 Gas-filled tubes

Segment indicator tubes, indicator tubes, dry reed contact units, thyratrons, industrial rectifying tubes, ignitrons, high-voltage rectifying tubes, associated accessories

T8 Picture tubes and components

Colour TV picture tubes, black and white TV picture tubes, colour monitor tubes for data graphic display, monochrome monitor tubes for data graphic display, components for colour television, components for black and white television and monochrome data graphic display

T9 Photo and electron multipliers

Photomultiplier tubes, phototubes, single channel electron multipliers, channel electron multiplier plates

- T10 Camera tubes and accessories
- T11 Microwave semiconductors and components
- T12 Vidicons and Newvicons
- T13 Image intensifiers
- T14 Infrared detectors

SEMICONDUCTORS (RED SERIES)

The red series of data handbooks comprises:

S10

51	Small-signal germanium diodes, small-signal silicon diodes, voltage regulator diodes(< 1,5 W), voltage reference diodes, tuner diodes, rectifier diodes
S2	Power diodes, thyristors, triacs Rectifier diodes, voltage regulator diodes (> 1,5 W), rectifier stacks, thyristors, triacs
S3	Small-signal transistors
S4a	Low-frequency power transistors and hybrid modules
S4b	High-voltage and switching power transistors
S 5	Field-effect transistors
S6	R.F. power transistors and modules
S 7	Microminiature semiconductors for hybrid circuits
S8	Devices for optoelectronics Photosensitive diodes and transistors, light-emitting diodes, displays, photocouplers, infrared sensitive devices, photoconductive devices.
S9	Power MOS transistors

Wideband transistors and wideband hybrid IC modules

INTEGRATED CIRCUITS (PURPLE SERIES)

The purple series of data handbooks comprises:

EXISTING SERIES

IC1	Bipolar ICs for radio and audio equipment
IC2	Bipolar ICs for video equipment
IC3	ICs for digital systems in radio, audio and video equipment
IC4	Digital integrated circuits CMOS HE4000B family
IC5	Digital integrated circuits — ECL ECL10 000 (GX family), ECL100 000 (HX family), dedicated designs
IC6	Professional analogue integrated circuits
IC7	Signetics bipolar memories
IC8	Signetics analogue circuits
IC9	Signetics TTL logic
IC10	Signetics Integrated Fuse Logic (IFL)
IC11	Microprocessors, microcomputers and peripheral circuitry

NEW SERIES

IC01N Radio, audio and associated systems

Bipolar, MOS

ICO2N Video and associated systems

Bipolar, MOS

IC03N Telephony equipment

Bipolar, MOS

IC04N HE4000B logic family

CMOS

IC05N HE4000B logic family uncased integrated circuits

CMOS

IC06N PC54/74HC/HCU/HCT logic families

HCMOS

IC07N PC54/74HC/HCU/HCT uncased integrated circuits

HCMOS

IC08N 10K and 100K logic family

ECL

ICO9N 54/74: STD, LS, S, F logic series

TTL

IC10N Memories

MOS, TTL, ECL

IC11N Analogue - industrial

IC12N Semi-custom gate arrays & cell libraries

ISL, ECL, CMOS

IC13N Semi-custom integrated fuse logic

IFL series 20/24/28

IC14N Microprocessors, microcontrollers & peripherals

Bipolar, MOS

Note

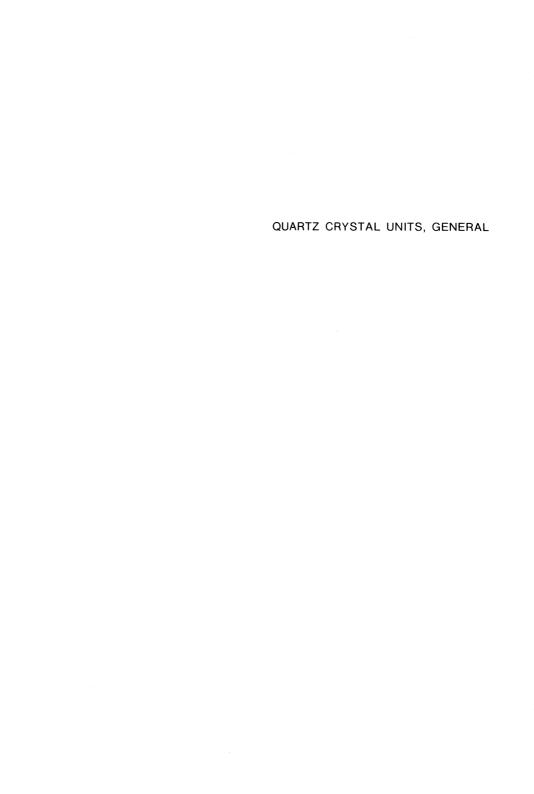
Books available in the new series are shown with their date of publication.

(published 1984)

COMPONENTS AND MATERIALS (GREEN SERIES)

The green series of data handbooks comprises:

C1	Assemblies for industrial use PLC modules, PC20 modules, HNIL FZ/30 series, NORbits 60-, 61-, 90-series, input devices, hybrid ICs
C2	Television tuners, video modulators, surface acoustic wave filters
С3	Loudspeakers
C4	Ferroxcube potcores, square cores and cross cores
C5	Ferroxcube for power, audio/video and accelerators
C6	Synchronous motors and gearboxes
C7	Variable capacitors
C8	Variable mains transformers
С9	Piezoelectric quartz devices Quartz crystal units, temperature compensated crystal oscillators, compact integrated oscillator quartz crystal cuts for temperature measurements
C10	Connectors
C11	Non-linear resistors Voltage dependent resistors (VDR), light dependent resistors (LDR), negative temperature coefficient thermistors (NTC), positive temperature coefficient thermistors (PTC)
C12	Variable resistors and test switches
C13	Fixed resistors
C14	Electrolytic and solid capacitors
C15	Film capacitors, ceramic capacitors
C16	Permanent magnet materials
C17	Stepping motors and associated electronics
C18	D.C. motors
C19	Piezoelectric ceramics
C20	Wire-wound components



QUARZ CRYSTAL UNITS

SURVEY OF TYPES

Quartz crystals, economy range in RW-43 holder

frequency*	lead length** mm	application	catalogue number	page
3000,000	12	general, e.g. microprocessors	4322 143/144	30
3276,800	12	timing (dividing ratio 2 ¹⁶ : 1 for 50 Hz)		
3440,000	12	general, e.g. microprocessors		
3440,000	12	general, e.g. microprocessors		
3547,000	12	video games		
3579,545	12	colour television		
3579,545	12	two-tone telephone dialling system		
3582,056	12	colour television, South America		
3686,400	12	general, e.g. microprocessors		
3686,400	12	general, e.g. microprocessors		
3750,000	12	video long play		
3840,000	12	general, e.g. microprocessors		
3932,160	12	timing (dividing ratio 2 ¹⁶ : 1 for 60 Hz)		
3997,676	12	general, e.g. microprocessors		
4000,000	12	general, e.g. digital tuners		
4000,000	12	colour television		
4000,000	12	clock control		
4000,000	12	colour television		
4096,000	12	timing (dividing ratio 2 ¹² : 1 for 1000 Hz)		
4194,304	12	clock control		
4194,304	12	clock		
4194,304	12	clock		
4233,600	12	compact disc		
4233,600	12	compact disc		
4250,000	12	chrominance subcarrier SECAM-L system		
4406,250	12	chrominance subcarrier SECAM-L system		
4433,619	12	sub-carrier oscillator PAL-system		
4433,619	5	video cassette recorders		
4433,619	5	colour television		
4435,571	5	colour television		
4500,000	12	video long play		
4531,468	12	video long play		
4608,000	12	general, e.g. microprocessors		
4782,720	12	two-tone telephone dialling system (high acc.)		
4782,720	12	two-tone telephone dialling system		
4865,000	12	general, e.g. microprocessors		

table continues on next page.

^{*} Quartz crystal units with other frequencies between 3000 and 16 000 kHz can be supplied on request.

^{**} Unless otherwise indicated the lead length is 12 mm. Available on request: 5 mm.

Quartz crystals, economy range, continued

frequency*	lead length**	application	catalogue number	page
kHz	mm			
4905,021 4905,021 4915,200 4915,200	12 5 12 12	measuring equipment video cassette recorders grammophone control system (high acc.) grammophone control systems	4322 143/144	30
5000,000 5068,800 5068,800 5068,800 5120,000 5120,000 5911,000	12 12 12 12 12 5 12	television cameras general, e.g. microprocessors general, e.g. microprocessors general, e.g. microprocessors carradio carradio video games		
6000,000 6000,000 6041,957 6144,000 6400,000	12 5 12 12 12	teletext viewdata, video cassette recorders teletext, viewdata, video cassette recorders teletext (USA) microprocessors microprocessors		
7000,000 7151,223 7159,090 7164,112	12 12 12 12	microprocessors sub-carrier colour television sub-carrier colour television sub-carrier colour television		
8000,000 8867,238 8867,238	12 12 5	general, e.g. microprocessors colour television, video cassette recorders colour television, video cassette recorders		
9830,400	12	measuring systems		1

Special types

High precision digital quartz temperature sensors in RW-43 holders in the frequency range of 4 to 20 MHz are described on page 36.

^{*} Quartz crystal units with other frequencies between 3000 and 16 000 kHz can be supplied on request.

^{**} Unless otherwise indicated the lead length is 12 mm. Available on request: 5 mm.

QUARTZ CRYSTAL UNITS

AT-cut quartz crystals for general frequency stabilization.

mode of	frequency		holder		catalogue	page
vibration	range MHz	type	housing	connections	number	
	3 to 10	RW-10 RW-33 RW-36	resistance welded resistance welded resistance welded	leads leads pins	4322 148 4322 148 4322 148	40 40 40
funda- mental	1 to 1,8 1,8 to 25	HC-6/U HC-27/U HC-27 ext. RW-33 RW-36	solder sealed all-glass all-glass resistance welded resistance welded	pins pins pins leads pins	4322 152	46 48 48 42 42
	4,5 to 25	HC-26/U HC-29/U RW-42 RW-43	all-glass all-glass resistance welded resistance welded	leads pins pins leads	4322 155 4322 155 4322 156 4322 156	52 52 35 35
	10 to 75	HC-27/U RW-33 RW-36	all-glass resistance welded resistance welded	pins leads pins	4322 159 4322 162 4322 162	56 60 60
third overtone	17 to 75	RW-42 RW-43	resistance welded resistance welded	pins leads	4322 161 4322 161	59 59
	20 to 75	HC-26/U HC-29/U	all-glass all-glass	leads pins	4322 160 4322 160	58 58
fifth overtone	50 to 125	HC-26/U HC-27/U HC-29/U RW-33 RW-36 RW-42	all-glass all-glass all-glass resistance welded resistance welded resistance welded	leads pins pins leads pins pins	4322 166	62 61 62 64 64 63
		RW-43	resistance welded	leads	4322 167	63

Special types

funda- mental	1 6,144 21,480	HC-6/U TO-39 RW-80	solder sealed resistance welded resistance welded	pins leads leads	4322 152 01241 4322 150 00011 4322 145 00011	47 44 38
third overtone	10 MHz high precision	HC-27/U	all-glass	pins	4322 159 00001	57

7th, 9th and 11th overtone crystals up to 250 MHz are available upon request.

INTRODUCTION

A quartz crystal unit consists of a quartz crystal element with electrodes, mounted in an enclosure with connecting pins or leads.

Units with pins are for mounting in sockets (not supplied by us) and those with leads are for printed-wiring board mounting. The usual lead-length is 12 mm which also permits flat mounting, whilst shorter leads (e.g. 5 mm) are for vertical mounting.

The quartz crystal element is a vibrating resonant plate which relies upon the piezoelectric effect to couple it to electrical circuits. The intrinsic properties of quartz make it a unique device for accurate and stable frequency control and selection. Although the properties of quartz (T.C., ageing, high Q-factor) are very stable, the ultimate performance of the element is largeley dependent on the environment and the associated electrical circuits. We strongly advise that a particular application be discussed with the crystal manufacturer at the earliest stage in any design.

Crystal elements are normally cut in the form of plates or bars. The dimensions of these elements and their orientation with respect to the axes of the crystal give the characteristic of the element. The dimensions are such that the mechanical resonance frequency equals the desired electrical frequency. There are a large number of crystal cuts but the most advantageous orientation is the so-called AT-cut. The frequency range that can be covered herewith is from 1 to 250 MHz. A practical range is from 1,8 to 125 MHz. The crystal element may vibrate in the frequency of a fundamental mode of vibration or in the third, fifth or higher overtone.

Our SC-cut quartz crystals are very suitable for use in ovens.

Several cuts specially for digital temperature measurements are applied as temperature sensors.

Note

All dimensional drawings are in mm unless otherwise indicated.



TERMS AND DEFINITIONS

in accordance with IEC 122-1

Resonance frequency f _r	The lower of the two frequencies of the crystal unit
	alone, under specified conditions, at which the

electrical impedance of the crystal unit is resistive.

Anti-resonance frequency f_a

The higher of the two frequencies of a crystal unit alone, under specified conditions, at which the

electrical impedance of the crystal unit is resistive.

Load resonance frequency f

One of the two frequencies of a crystal unit in

One of the two frequencies of a crystal unit in association with a series or with a parallel load capacitance, under specified conditions, at which the electrical impedance of the combination is resistive. This frequency is the lower of the two frequencies when the load capacitance is in series and the higher when it is in parallel (see Fig. 2). For a given value of load capacitance (C_L), these frequencies are identical for all practical purposes and given by:

$$\frac{1}{f} = 2\pi \sqrt{\frac{L_1C_1(C_0 + C_L)}{C_1 + C_0 + C_L}}$$

Nominal frequency f_n The frequency assigned by the specification of the crystal unit.

Working frequency $\mathbf{f}_{\mathbf{W}}$ The operational frequency of the crystal unit together

with its associated circuits.

Overall tolerance

The maximum permissible deviation of the working frequency from nominal frequency due to a specific cause or a combination of causes.

Adjustment tolerance The permissible deviation from the nominal frequency at the reference temperature under specified conditions.

Ageing tolerance The permissible deviation due to time under specified conditions.

Tolerance over the temperature range

The permissible deviation over the temperature range with respect to the frequency at the specified refe-

rance temperature.

Tolerance due to level of drive variation

The permissible deviation due to the variation of level of drive.

QUARTZ CRYSTAL UNITS

Sure over which the crystal unit must function with the specified tolerances. Operable temperature range The range of temperatures as measured on the encless use over which the crystal unit must function thou not necessarily within the specified tolerances. Reference temperature The temperature at which certain crystal measureme are made. For controlled temperature units, the reference temperature is the mid-point of the controlled temperature range. For non-controlled temperature units, the reference temperature is normally 25 ± 2 for the reference temperature is normally 25 ± 2 for the resistance of the crystal unit alone at the reson ance frequency f _r . Load resonance resistance R _L The resistance of the crystal unit in series with a stated external capacitance at the load resonance frequency f _L . Note: The value of R _L is related to the value of R _r by the following expression: R _L = R _r (1 + C ₀ /C _L) ² Level of drive A measure of the conditions imposed upon the crystal unit expressed in terms of power dissipated. Note: In special cases, the level of drive may be specified in terms of crystal current or voltage. Unwanted response A state of resonance of a crystal vibrator other than that associated with the working frequency. The effective external capacitance associated with the crystal unit which determines the load resonance frequency f _L . Ageing (long-term parameter variation) The relation which exists between any parameter (e.g. resonance frequency) and time. Note: Such parameter variation is due to long-term changes in the crystal unit and is usually expressed fractional parts per period of time. Motional capacitance C ₁ The capacitance of the motional (series) arm of the equivalent circuit.			
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are made. For controlled temperature units, the reference temperature is the mid-point of the controlled temperature range. For non-controlled temperature units, the reference temperature is normally $25 \pm 2^{\circ}$. Resonance resistance R _r The resistance of the crystal unit alone at the resonance frequency f _r . Load resonance resistance R _L The resistance of the crystal unit in series with a stated external capacitance at the load resonance frequency f _L . Note: The value of R _L is related to the value of R _r by the following expression: $R_L = R_r (1 + \frac{C_0}{C_L})^2$ Level of drive A measure of the conditions imposed upon the crystal unit expressed in terms of power dissipated. Note: In special cases, the level of drive may be specified in terms of crystal current or voltage. Unwanted response A state of resonance of a crystal vibrator other that that associated with the working frequency. Load capacitance C _L The effective external capacitance associated with the crystal unit which determines the load resonance frequency f _L . Ageing (long-term parameter variation) The relation which exists between any parameter (e.g. resonance frequency) and time. Note: Such parameter variation is due to long-term changes in the crystal unit and is usually expressed fractional parts per period of time. Motional capacitance C ₁ The capacitance of the motional (series) arm of the equivalent circuit.	Operable temper	ature range	The range of temperatures as measured on the enclosure over which the crystal unit must function though not necessarily within the specified tolerances.
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equivalent circuit.			changes in the crystal unit and is usually expressed in
Motional inductance L ₁ The inductance in the motional (series) arm of the	Motional capacit	ance C ₁	The capacitance of the motional (series) arm of the equivalent circuit.
equivalent circuit.	Motional inducta	ance L ₁	The inductance in the motional (series) arm of the equivalent circuit.

ELECTRICAL PROPERTIES AND BEHAVIOUR

CRYSTAL UNIT EQUIVALENT CIRCUIT

The equivalent circuit, which has the same impedance as the unit in the immediate neighbourhood of resonance, is usually represented by an inductance, capacitance and resistance in series, this series branch being shunted by the capacitance between the terminals of the unit. The parameters of the series branch are usually given by L_1 , C_1 and R_1 . The parallel capacitance is given by C_0 (see Fig. 1).

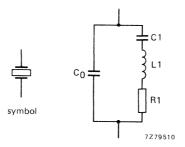


Fig. 1 Crystal unit equivalent circuit.

The parameters of the series branch are termed the "motional parameters" of the crystal unit. The parameter C_0 is termed the "parallel capacitance".

The equivalent circuit has two resonance frequencies at which the electrical impedance is resistive: the "resonance frequency f_r " and the "anti-resonance frequency f_a ". The resistance of the equivalent circuit at the resonance frequency f_r is termed the "resonance resistance R_r ".

For R₁ $\ll \frac{1}{\omega c_0}$ the following relations hold:

$$f_r = \frac{1}{2\pi\sqrt{L_1C_1}} \tag{1}$$

$$f_{a} = \frac{1}{2\pi\sqrt{L_{1} \frac{C_{1}C_{0}}{C_{1} + C_{0}}}}$$
 (2)

$$R_r = R_1 \tag{3}$$

QUARZ CRYSTAL UNITS

LOAD CAPACITANCE AND FREQUENCY PULLING

During manufacture, definable limits are set to the accuracy of frequency. In an oscillator, a load capacitance C_L is required to trim the working frequency f_W to the nominal frequency f_{Ω} . Figure 2 shows the crystal unit equivalent circuit with a load capacitance in series and in parallel. Each combination has two resonance frequencies at which the electrical impedance of the circuit is resistive. The lower of the two frequencies, when the load capacitance is connected in series and the higher, when it is connected in parallel are termed "load resonance frequencies f_L ". At the frequency f_L the resistance of the combination with the load capacitance in series is termed "load resonance resistance R_L ". For $R_1 \ll 1/\omega C_0$:

$$f_{L} = \frac{1}{2\pi \sqrt{L_{1} \frac{C_{1}(C_{0} + C_{L})}{C_{1} + (C_{0} + C_{L})}}}$$
(4)

$$R_L = R_r \left(1 + \frac{C_0}{C_L}\right)^2$$
 * (5)

For a given value of C_L the load resonance frequencies of the series and the parallel combinations are identical.

In practice, however, the parallel combination shown in Fig. 2c rarely occurs in an oscillator. From equation (4) two second parameters of vital concern can be derived: the difference between load resonance frequency f_L and resonance frequency f_r , " Δf ", and the relative change in frequency as a function of the change in load capacitance, termed "pulling sensitivity S".

"Δf"

$$\Delta f = f_{L} - f_{r} \tag{6}$$

with f₁ from equation (4)

$$\Delta f = \frac{1}{2} f_r \frac{C_1}{C_0 + C_L} - \frac{\Delta f^2}{2 f_s}$$
 (7)

and to a close approximation

$$\Delta f = \frac{\gamma_2}{r} f_r \frac{C_1}{C_0 + C_L}$$
 (8)

Equation (8) greatly simplifies calculations and methods of measurement, whilst the error is negligible in nearly all cases.

$$R_{L par} = \frac{1}{R_{1}.\omega_{r}^{2}(C_{0} + C_{L})^{2}}$$

^{*} The resistance of the combination with the load capacitance in parallel is given by

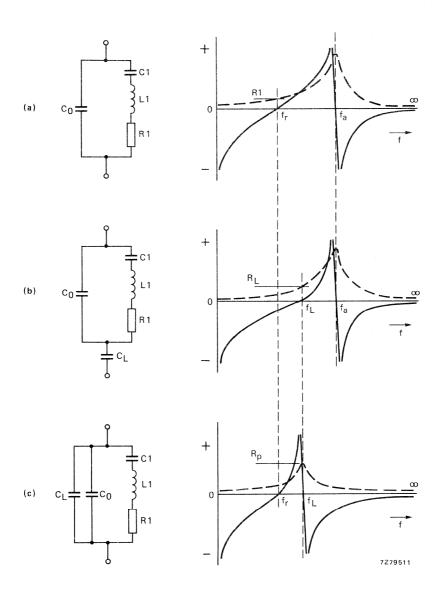


Fig. 2 Resonance, anti-resonance and load resonance frequency.

---- reactance

--- resistance

QUARTZ CRYSTAL

Pulling sensitivity S

$$S = \frac{1}{f_L} \left(\frac{\delta f}{\delta C_L} \right)_{f = f_L} = + \frac{1}{f_L} \cdot \frac{\delta \Delta f}{\delta C_L}$$

with Δf from equation (8)

$$S = -\frac{1}{2} f_r \frac{C1}{(C_0 + C_1)^2} \cdot \frac{1}{f_1}$$
 (9)

and to a close approximation

$$S = -\frac{C1}{2(C_0 + C_L)^2}$$
 (10)

Standard values of load capacitance

The standard values of load capacitance for crystal units operating at the fundamental frequency of the mode are:

Note that in some countries 32 pF is still in use, but this value should not be considered as a standard value and its use is not recommended.

In special cases, load capacitances of the values 8, 12 and 15 pF may be used for fundamental mode crystal units.

Overtone crystals are often operated at series resonance. Where a load capacitance is used, it should be chosen from the following standard values:

The pulling sensitivity expressed in 10^{-6} /pF is a good measure for the frequency sensitivity as a function of load capacitance variations at the working frequency.

Figure 3 illustrates Δf and the pulling sensitivity S as a function of the load capacitance, for two quartz crystals having different C₁ values. It should be noted that a tolerance of ½ pF on a 20 pF load capacitance may lead to an error of \pm 11.10⁻⁶.

Crystal (a)	Crystal (b)
$f_r = 10000,000 \text{ kHz}$	$f_r = 10000,000\text{kHz}$
C ₀ = 5 pF	$C_0 = 2 pF$
C ₁ = 28 fF	$C_1 = 5.6 \text{ fF}$
C _L = 20 pF	$C_L = 20 pF$
f _L = 10 005,600 kHz	$f_L = 10001,273\text{kHz}$
$S = -22.4.10^{-6}/pF$	$S = -5.79.10^{-6}/pF$

Specified, or in special cases, measured Δf and S, as given for crystal (a) in Table 1, offer a simple direct quidance.

Table 1

nominal frequency $f_n = f_L$	10 000,000 kHz	
nominal load capacitance CL	20 pF	
	specified	measured
Δf	5,600 kHz	5,700 kHz
pulling sensitivity S	$-22 \pm 2 \times 10^{-6}/pF$	-22,4 x 10 ⁻⁶ /pF

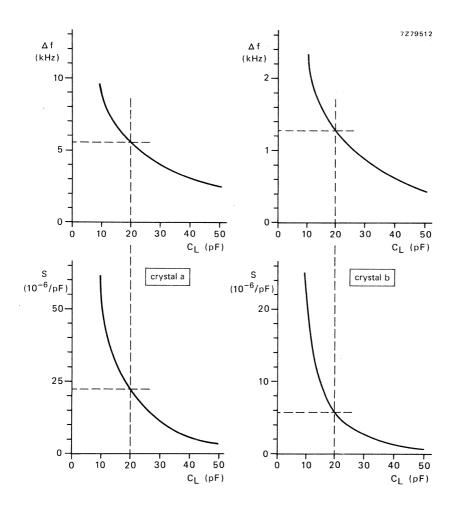


Fig. 3 $\,\Delta f$ and pulling sensitivity as a function of the load capacitance. Tolerances on the parameters f_r , C_0 and C_1 are required for calculating the " Δf " and the "pullability at f_n ".

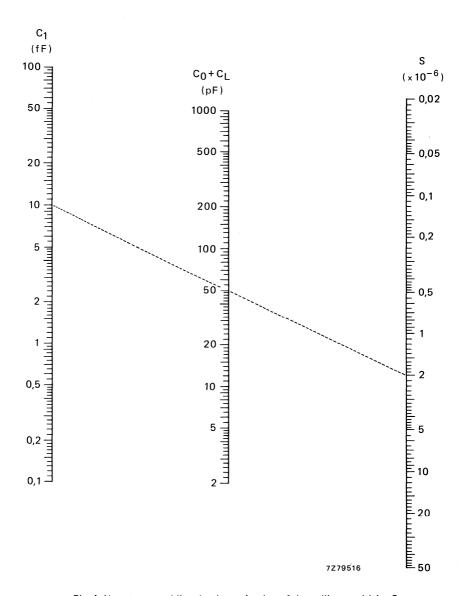
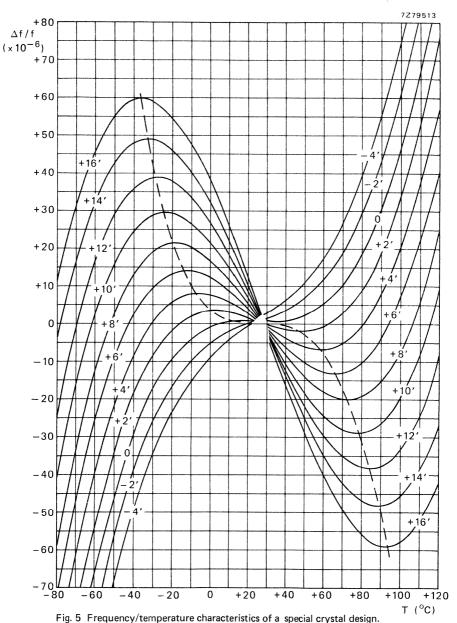


Fig. 4 Nomogram enabling the determination of the pulling sensitivity S.



rig. 5 Prequency/temperature characteristics of a special crystal design

QUARTZ CRYSTAL UNITS

LEVEL OF DRIVE

The power dissipated in a crystal unit is termed "level of drive" and is usually expressed in mW. In the level of drive range 10⁻¹² to 10⁻³ W the drive level dependency of the crystal unit characteristics is almost negligible. For drive level greater than approximately 0,5 mW, the crystal unit characteristics tend to change. For this reason the crystal unit characteristics are specified at a level of drive of 0,5 mW.

Low drive levels

When a crystal oscillator is switched on, there will initially be some noise in the circuit. The noise power, which depends on the circuit design and on the components used, will be in the region of 10^{-16} W. From this level, the oscillatory power builds up in the crystal unit, passing through a power range of approximately 12 decades to its maximum value. At the extremely low power levels that occur during build up of oscillation, the resonance resistance R_r may increase slightly. The crystal oscillator should, therefore, have sufficient loop gain to avoid start-up problems.

High drive levels

For applications requiring high stability, a drive level between 5 μ W and 0,5 mW should be used. Drive levels greater that 0,5 mW should be avoided, and excessively high drive levels (greater than say 5 mW) may seriously affect the crystal's behaviour.

FREQUENCY/TEMPERATURE CHARACTERISTICS

The frequency drift as a function of temperature can be represented by a graph, the T.C. curve or drift characteristic. In the case of AT cuts, the relation of drift and temperature is approximated by a cubic curve; the drift characteristic of the other cuts is parabolic.

Figure 5 shows a number of frequency-temperature curves obtained from AT-cut crystals with various angles of cut α (from -4' to + 16' increasing angle of cut). The curves are symmetrical with respect to 27 °C, and it is not possible to shift this point. A temperature range which is fairly symmetrical with respect to 27 °C (e.g. 0 - 60 °C) will, therefore, result in the smallest frequency drift in that range. A small frequency drift over a wide temperature range, e.g. -40 to + 80 °C, will result in a quite steep temperature coefficient at room temperature.

It will be evident that, for AT-cut crystals, the angle of cut and its accuracy are decisive for the frequency drift over a given temperature range.

ADVANTAGES OF ALL-GLASS HOLDERS

Crystal units with all-glass holders show the following advantages over those with metal holders:

- (a) a lower series resistance, which also means a higher Q-factor, thanks to the fact that glass holders are evacuated giving less mechanical damping;
- (b) better performance under adverse climatic conditions;
- (c) a higher frequency stability.

AGEING

A non-reversible, mostly gradual change with time in resonance frequency is called (an effect of) ageing. Only where very good long-term stability is required should ageing be of consequence. It should be borne in mind that (with a view to ageing only):

- (a) crystal units having an all-glass holder are preferred to those having a metal holder;
- (b) low frequency crystals are favourable preferred to high frequency crystals having the same crystal cut;
- (c) overtone crystals are preferred to fundamental crystals for the same frequency (or fifth overtone compared with third overtone crystals).

CRYSTAL BEHAVIOUR IN AN OSCILLATOR

In the vicinity of resonance the impedance of a quartz crystal unit can be represented by a circle (see Fig. 6). The circle is shifted downwards with respect to the resistance axis over

$$X_0 = \frac{1}{2\pi f_r C_0}.$$

When a load capacitance is connected in series with the unit the shift is $X_0 + X_1$, where

$$X_{L} = \frac{1}{2\pi f_{L}C_{L}}.$$

The difference between anti-resonance frequency and resonance frequency

$$\mathsf{f}_a - \mathsf{f}_r \approx \frac{\mathsf{C}_1}{2\mathsf{C}_0} \;.\; \mathsf{f}_r \;.\; \frac{\mathsf{C}_L}{\mathsf{C}_0 + \mathsf{C}_L}$$

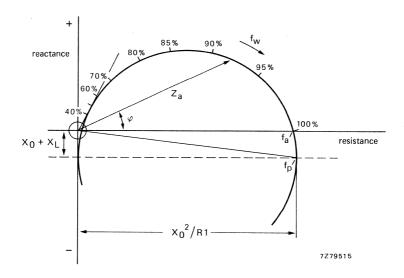
is assumed to be 100%.

It can be seen that the difference between the two frequencies, determined by the phase angle φ , disappears at $f_W = 50\%$. The phase angle in the oscillator should be kept sufficiently small to avoid crystal unit operation in the uncertain 50% area (frequency switching).

Quartz crystal units for frequencies higher than 100 to 125 MHz (depending on type) have an impedance circle with a greater downwards shift, even to below the real axis. When the figure of merit given by

$$M = \frac{X_0}{R_1} = \frac{1}{(2\pi f_r) R_1 C_0}$$

is less than approximately 5, the resonance frequency fr is arbitrary.



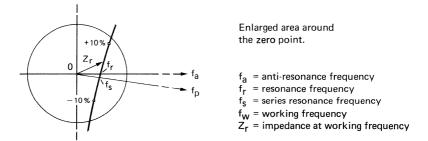


Fig. 6 Working frequency and impedance of a quartz crystal unit in the impedance diagram.

Indications for use

Keep phase deviations in the circuit sufficiently low to avoid crystal unit operation in the 50% working frequency area, in particular when phase variation is used for frequency pulling (P.L.L. system).

Ensure that amplification is sufficiently high, in particular when applying phase variation.

Keep crystal unit drive level low (generally ≤ 0,5 mW), see Fig. 7.

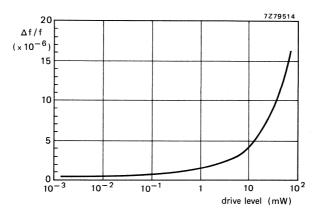


Fig. 7.

MEASURING PROCEDURES

Several methods of measuring quartz crystal units are in use.* Because different methods may give different results, our measuring procedure is given below. This is the passive method with π -network according to IEC publication 444. Further, the method is mentioned with crystal test oscillator type 150A, (make Saunders), which is recommended if a frequency correlation of 2 to 5 x 10⁻⁶ is tolerable. The accuracy of reproduction of the π -network method ranges between 10⁻⁶ and 10⁻⁸ depending on the type of crystal unit to be measured. The π -network method can be extended for measuring crystal unit parameters very accurately. This is achieved by a slight modification of the π -network, the use of precision reference resistors and two precision high-frequency load capacitors.

PASSIVE METHOD WITH π -NETWORK (IEC)

The principle of this method is very simple. With the equipment shown in the block diagram of Fig. 1, a stable signal source (frequency synthesizer) is adjusted to the frequency at which the signal has zero phase change when passing through the crystal as measured by the phase meter; this frequency (measured with the frequency counter) is then the resonance frequency of the crystal.

For ease of operation, it is possible to phase-lock the system by feeding back the analogue output of the phase error (from zero) to control the precise frequency of the signal source (A.F.C. loop shown by dashed line).

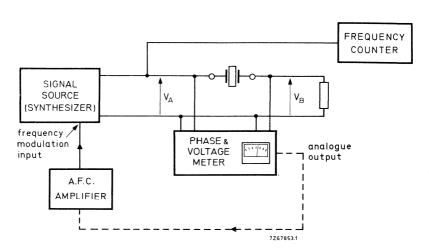


Fig. 1.

* The following measuring methods can be applied on request for the time the obsolete equipment is available:

Method using Crystal Test Set, type TS193A (British Military Standard). Method using Crystal Impedance Meter TS330/TSM (U.S. Army Standard). Method using Crystal Impedance Meter TS683/TSM (U.S. Army Standard).

π-network

The first departure which must be made from the simple system of Fig. 1 is the test jig for holding the crystal. The test jig consists of two π -connected resistive pads, carefully manufactured to represent a pure, constant resistance, which is frequency insensitive at the terminals of the quartz crystal (see Fig. 2).

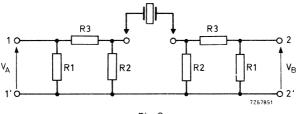


Fig. 2.

The function of the input and output'pads' is twofold:

- (a) to match the crystal impedance to the associated equipment,
- (b) to attenuate reflections from the associated equipment.

For further particulars consult IEC recommendations, Publication 444.

Quartz crystal parameter measurements

A 5 pF trimming capacitor should be connected in parallel with each of the resistors R2 for accurate compensation of the transmission circuit. A shield is mounted between the contacting plates to reduce the capacitance between them. Two measuring procedures for crystal parameter measurement with the modified π -network are in use:

The C₁ method

In general, this method is used for fundamental mode crystal units with frequencies up to 25 MHz.

Precision load capacitors are inserted in the π -network. Load resonance frequency and load resonance resistance can then be measured directly. C1 can be calculated.

The impedance method

Generally this method is used for higher frequencies up to approximately 125 MHz.

Phase and impedance are measured, all other parameters can be calculated by means of a computer.

Crystal shielding

Depending on the application, crystal shielding may give rise to frequency deviations, in particular for fundamental mode crystal units with a considerable pulling sensitivity.

In our procedure the metal enclosure of the crystal unit normally is not earthed. If, in special cases, earthing is required this should be mentioned in the specification for ordering.

METHOD WITH CRYSTAL TEST OSCILLATOR 150A AND PRINTER PROCESSOR 2000A

Initial calibration

The accuracy of the crystal test oscillator is for a considerable part determined by the alignment of the capacitance meter. Alignment and check of the capacitance meter by means of a stable precision 75 pF capacitor is recommended. For further particulars see 150 A manual.

QUARTZ CRYSTAL UNITS AS DIGITAL TEMPERATURE SENSOR

The most well-known applications of quartz crystal units are those where the crystal is used in oscillator and filter circuits, as a frequency-selective element with an extremely high Q-factor. By correct choice of the cutting angle of the vibrating plate, it is possible to obtain a very low TC over a limited temperature range.

Examples of such crystal cuts are: AT, BT, CT and GT cuts.

On the other hand, it is also possible to cut crystal plates in such a way that the resonance frequency is an almost linear function of the temperature. In fact, the very first discovered quartz crystal cut, the "Y-cut", was such a cut.

There are, however, some disadvantages which make this cut less suitable for temperature sensing.

How to use a quartz crystal unit as a temperature sensor

To be able to measure temperatures with a quartz crystal sensor, the device should be connected to an oscillator circuit which usually consists of one or two transistors or an integrated circuit. The oscillator will produce an output signal whose frequency will change by -40 to $+80 \cdot 10^{-6}$ /K, depending on the cutting angle. There are several possible ways of processing this signal as shown in Figs 1 to 4.

Thanks to the excellent stability, the low ageing and its 'digital' nature, resolutions of 0,01 K are easy to achieve without noise problems. This renders the device particular suitable for measurements of very small temperature differences as in distillation columns and flow meters.

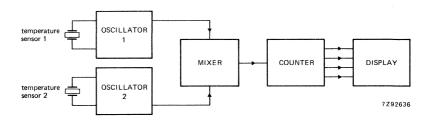


Fig. 1.

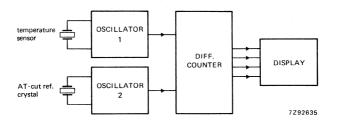


Fig. 2.

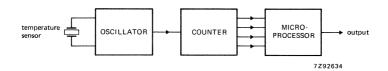


Fig. 3.

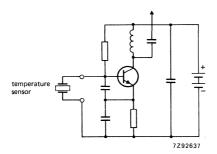


Fig. 4 Miniature wireless temperature sensor.

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March 1984

QUARTZ CRYSTAL UNITS

HOW TO SPECIFY A QUARTZ CRYSTAL UNIT

When ordering quartz crystal units for which a catalogue number (12 digits) has been fixed, please quote catalogue numbers as stated in this Data Handbook.

For quotation or ordering a quartz crystal unit which still has no complete catalogue number the supplier needs to know certain basic information. Please use the following check list.

Type of crystal unit

Type of holder

Nominal frequency kHz

Mode of vibration fundamental or third fifth overtone

Permissible deviation from nominal frequency

(adjustment tolerance) at + 25 °C x 10⁻⁶

Temperature range from to °C

Frequency drift over specified temperature range x 10⁻⁶

Circuit conditions:

resonant frequency f_r or kHz load resonant frequency f_L and kHz load capacitance C_L pF maximum resonance resistance R_r or Ω maximum load resonance resistance R_I

Crystal unit equivalent parameters

 $\begin{array}{ccc} C_1 & \text{ fF} \\ C_0 & \text{ pF} \\ R_1 & \Omega \\ L_1 & \text{ mH} \\ \text{Level of drive} & \text{ mW} \end{array}$

Ageing $\Delta f/f$ per month or year x 10⁻⁶

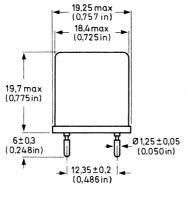
Mechanical requirements/tests

MARKING

The marking on the unit includes the nominal frequency by means of 7 or 8 figures, in kHz in the case of fundamental crystals and in MHz in the case of overtone crystals. Other figures include the five last digits of the catalogue number. The last digit printed on the unit may, however, be different. Also a manufacturing date is stated, referring to the year and month of manufacture, e.g. 424 means the 24th week of 1984.

HOLDERS

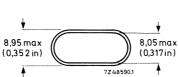
ALL-GLASS HOLDERS

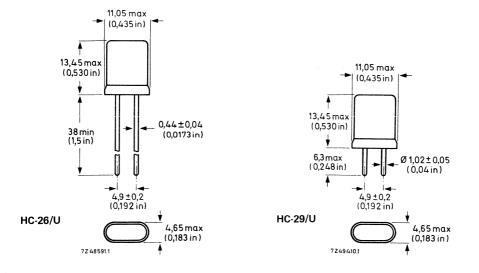


Dimensions in mm (in inches between brackets)

HC-27/U

(IEC type DB is identical except for the height which is 26 mm max, instead of 19,7 max.).

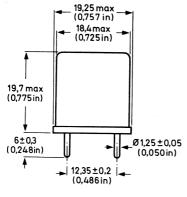




QUARTZ CRYSTAL UNITS

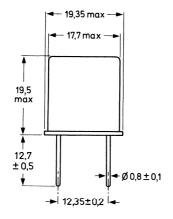
METAL HOLDERS

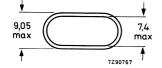
Dimensions in mm (in inches between brackets)



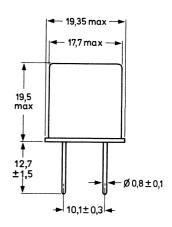
8,95 max (0,352 in) 8,05 max (0,317 in)

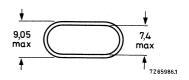
HC-6/U, solder sealed RW-36, resistance welded



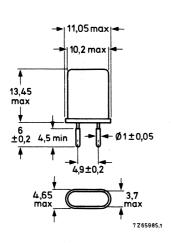


RW-33 resistance welded

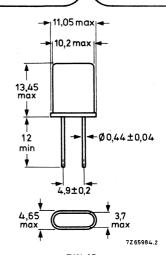




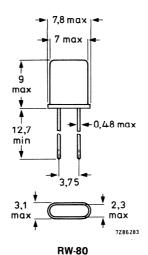
RW-10 resistance welded



RW-42 resistance welded



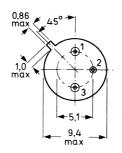
RW-43 resistance welded

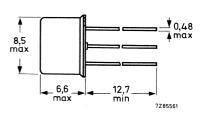


resistance welded

TO-39 Resistance welded

Pin 2 is connected to the case.





CORRESPONDING IEC AND DIN TYPE NUMBERS

	IEC 122-3	DIN 45110
HC-6/U	AA	K1A
HC-26/U	CY	R2A
HC-27/U	DA	Q1A
HC-27/U, extended	DB	Q1B
HC-29/U	CZ	R1A
RW-10	DS	K4A
RW-33		_
RW-36	_	КЗА
RW-42	DQ	МЗА
RW-43	DP	M4A
RW-80	35/EB	N4B
TO-39	17/CK	T1A

QUARTZ CRYSTAL UNITS, ECONOMY TYPES

economy types in RW-43 holder

QUICK REFERENCE DATA

Nominal frequency	3000,000 to 16 000,000 kHz
Mode of vibration	fundamental
Type of holder	RW-43

APPLICATION

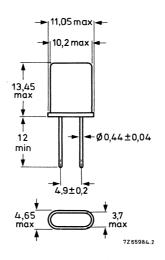
See Table 1.

DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder RW-43 and has two connecting leads. See also "general" section.

MECHANICAL DATA

Outlines



RW-43

Mass 2 g approximately

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Resonance resistance of unwanted response

> 2 R_r

Insulation resistance

max. $10^{10}\,\Omega$

Permissible d.c. voltage between leads

max, 100 V

See Table 1 for other parameters

TESTS AND REQUIREMENTS

IEC 122	IEC 68-2	test	procedures	requirements
	12000-2	test	procedures	requirements
2.5.17	Ва	aging	1000 h + 100 °C	$\Delta f_r \le 5 \times 10^{-6}$ $\Delta R \le 20\%$
2.5.12 2.5.13	Db	accelerated damp heat	+ 25 to + 55 °C, 6 cycles 95 to 100% R.H.	$\Delta f_r \leqslant 5 \times 10^{-6}$
2.5.14				$\Delta R \leqslant 20\%$
	Na	temperature cycling test	40/+ 125 °C, 10 cycles, 1 h/cycle	$\Delta f_r \le 5 \times 10^{-6}$ $\Delta R \le 20\%$
2.5.2	Ea	shock	100g sawtooth 6 shocks, 3 directions	$\Delta f_r \le 5 \times 10^{-6}$ $\Delta R \le 20\%$
2.5.3	Fc	vibration	10-500-10 Hz, 10g 3 h, 3 directions	$\Delta f_r \le 5 \times 10^{-6}$ $\Delta R \le 20\%$
	Tb	resistance to soldering heat	3 s, 350 °C	≤ 5 x 10 ⁻⁶ ≤ 20%
2.5.6	Ub	bending of terminations	1 x 90°, 5 N	no visible damage
	Eb	bump	3000 bumps, 30g	$\Delta f_r \leqslant 5 \times 10^{-6}$ $\Delta R \leqslant 20\%$
	Ed	free fall	3 x 0,75 m on steel	$\Delta f_r \le 5 \times 10^{-6}$ $\Delta R \le 20\%$
	Q, Qk	sealing	16 h, 700 kPa He	< 10 ⁻⁸ ncc/s He

Table 1
Specifications of quartz crystal units in RW-43 holder; economy range

	f	CL	7		R _r	Со
load resonance	adjustment	load	temperature	frequency	resonance	static parallel
frequency	tolerance	capacitance	range	tolerance	resistance	capacitance
kHz	< ± · 10 ⁻⁶	pF	oC	< ± · 10 ⁻⁶	Ω	pF
3000,000	40	20	-20 to + 70	30	150	4,0
3276,800	40	20	-20 to + 70	30	100	4,3
3440,000	40	20	-40 to +80	30	100	4,3
3440,000	40	30	-40 to + 80	30	100	4,3
3547,000	30	30	10 to + 60	20	100	4,5
3579,545	40	20	-20 to + 70	30	100	4,5
3579,545	5000	series	-20 to + 70	100	100	4,5
3582,056	40	20	-10 to + 60	25	100	4,5
3686,400	40	30	-10 to + 60	25	100	4,5
3686,400	20	series	-20 to + 70	40	100	4,5
3750,000	30	13	-10 to + 65	7	75	4,5
3840,000	20	30	-20 to + 70	50	75	4,6
3932,160	30	17	-40 to +90	50	75	4,7
3997,676	40	20	0 to + 60	15	75	2,8
4000,000**	40	30	-10 to + 60	25	75	2,8
4000,000	40	20	-10 to $+60$	25	75	2,8
4000,000	40	30	0 to + 60	15	75	2,8
4000,000	30	20	-10 to + 60	40	75	2,8
4096,000	50	20	-40 to +90	50	60	5,0
4194,304	40	12	10 to + 60	25	60	2,9
4194,304	40	11,4	-10 to + 60	25	60	2,9
4194,304**	50	20	-40 to +80	50	90	2,9
4233,600	40	series	-20 to + 70	30	60	5,2
4233,600	40	30	-20 to + 70	30	60	5,2
4250,000	40	20	-10 to $+60$	25	60	5,2
4406,250	40	20	-10 to $+60$	25	60	5,4
4433,619**	40	20	10 to + 60	25	60	5,5
4433,619**	40	20	+ 10 to + 55	15	60	5,5
4433,619**	40	20	-10 to + 60	25	60	5,5
4435,571	40	20	-10 to $+60$	25	60	5,5
4500,000	30	13	-10 to +65	7	60	5,6
4531,468	30	13	-10 to +65	7	60	5,6
4608,000	30	series	0 to + 70	40	60	5,8
4782,720	40	series	-20 to + 70	30	60	5,7
4782,720	5000	series	-20 to + 70	100	60	5,7
4865,000	50	series	-20 to + 70	50	60	5,7

Table continues on next page.

^{*} The standard lead length is 12 mm (5 mm on request). Types marked by * have a standard lead length of 5 mm.

^{**} Preferred types.

C ₁ motional capacitance fF	S pullability >· 10 ⁻⁶ /pF	application	catalogue number 4322 143 or 4322 144 followed by
10,0	8	general, e.g. microprocessors	04411
13,5	7	timing (dividing ratio 2 ¹⁶ : 1 for 50 Hz)	04421
13,5	9	general, e.g. microprocessors	04571
13,5	4	general, e.g. mircroprocessors	04761
14,5	5	video games	04491
14,7	10	colour television	04391
14,7		two-tone telephone dialling system	04401
14,7	10	colour television, South America	04381
15,0	5	general, e.g. microprocessors	04371
15,0	_	general, e.g. microprocessors	04551
15,0	22	video long play	04431
15,4	5	general, e.g. microprocessors	04441
15,8	14	timing (dividing ratio 2 ¹⁶ : 1 for 60 Hz)	04671
11,0	7	general, e.g. microprocessors	04481
11,0	3	general, e.g. digital tuning	04091
11,0	9	colour television	04261
11,0	3	clock control	04271
11,0	9	colour television	04881
18,5	12	timing (dividing ratio 2 ¹² : 1 for 1000 Hz)	04701
11,6	22	colour control	04071
11,6	24	clock	04081
11,6	9	clock	04471
16,7		compact disc	04461
16,7	6	compact disc	04561
16,7	12	chrominance subcarrier SECAM-L system	04361
20,5	15	chrominance subcarrier SECAM-L system	04351
20,6	12	sub-carrier oscillator PAL-system	04041
20,6	12	video cassette recording	04251*
20,6	12	colour television	04281*
20,6	12	colour television	04871*
18,4	22	video long play	04111
18,4	22	video long play	04121
22,0	_	general, e.g. microprocessor	04341
21,4	_	two-tone telephone dialling system (high acc.)	04031
21,4		two-tone telephone dialling system	04291
22,5		general, e.g. microprocessors	04781

Table 1
Specificationes of quartz crystal units in RW-43 holder; economy range

	f	CL	1	Ī	R _r	co
load resonance	adjustment	load	temperature	frequency	resonance	static paralle
frequency	tolerance	capacitance	range	tolerance	resistance	capacitance
kHz	< ± · 10 ⁻⁶	pF	°C	< ± · 10 ⁻⁶	Ω	pF
4905,021	40	20	-20 to + 70	30	60	5,9
4905,021**	40	20	-20 to + 70	30	60	5,9
4915,200	20	30	+ 5 to + 45	20	60	3,2
4915,200	2000	30	+ 5 to + 45	20	60	3,2
5000,000	40	20	-20 to + 70	30	60	3,2
5068,800	40	20	-20 to + 70	30	60	3,2
5068,800	40	series	-20 to + 70	30	60	3,2
5068,800	20	series	-15 to + 70	30	60	3,2
5120,000	40	20	-20 to + 70	30	60	3,5
5120,000	40	20	-20 to + 70	30	60	3,5
5911,000	20	30	-10 to + 60	20	60	3,7
6000,000**	40	20	-20 to + 70	30	60	6,9
6000,000**	40	20	-20 to + 70	30	60	6,9
6041,957	40	20	-20 to + 70	30	60	6,9
6144,000	50	20	0 to + 70	50	60	3,8
6400,000	40	20	20 to + 70	25	60	4,0
7000,000	40	20	10 to + 60	30	60	4,2
7151,223	40	20	-10 to + 60	25	60	4,4
7159,090	40	20	10 to + 60	25	60	4,4
7164,112	40	20	-20 to + 70	25	60	4,4
8000,000	40	20	-20 to + 70	25	60	5,0
8867,238**	40	20	10 to + 60	25	60	5,5
8867,238	40	20	10 to + 60	25	60	5,5
9830,400	50	series	0 to + 70	50	50	5,7

^{*} The standard lead length is 12 mm (5 mm on request). Types marked by * have a standard lead length of 5 mm.

^{**} Preferred types.

C ₁ motional	S pullability	application	catalogue number 4322 143 or
capacitance fF	>·10 ⁻⁶ /pF		4322 144 followed by
22,9	13	measuring equipment	04601
22,9	13	video cassette recording	04131*
13,6	5	grammophone control systems (high acc.)	04141
13,6	5	grammophone control systems	04201
13,8	12	television cameras	04151
14,0	12	general, e.g. microprocessors	04331
14,0	_	general, e.g. microprocessors	04451
14,0	_	general, e.g. microprocessors	04541
14,6	11	carradio	04161
14,6	11	carradio	04751*
16,5	6	video games	04521
27,6	17	teletext, viewdata, video cassette recording	04101
27,6	17	teletext, viewdata, video cassette recording	04531*
27,6	17	teletext (USA)	04591
17,0	12	microporcessors	04321
18,0	12	microprocessors	04311
19,2	12	microprocessors	04791
19,5	14	sub-carrier colour television	04171
19,5	14	sub-carrier colour television	04181
19,5	14	sub-carrier colour television	04191
21,0	15	general, e.g. microprocessors	04301
22,0	16	colour television, video cassette recording	04051
22,0	16	colour television, video cassette recording	04221*
25,3	_	measuring systems	04611

LOW COST HIGH PRECISION DIGITAL QUARTZ TEMPERATURE SENSORS

DESCRIPTION

The sensor consists of a metal-plated special T.C.-cut piezoelectric quartz plate, mounted in a hermetically-sealed, resistance-welded metal holder, with two leads. The holder is filled with a dry inert gas. The quartz plate oscillates in a fundamental thickness-shear mode. The resonance frequency is an almost linear function of the temperature. See also section "General".

Features

- no A/D conversion
- excellent linearity
- high stability, very low ageing
- wide temperature range
- high noise immunity
- easy calibration
- quantity production at low cost

APPLICATIONS

These sensors can be used in industrial temperature measurement and control, car electronics, flow meters, weather balloons, medical systems and in energy saving projects such as heat monitors and solar panels.

QUICK REFERENCE DATA

	economy design	special design	
Frequency range	4 to 20	1 to 25	MHz
Temperature range	-100 to + 150	-100 to + 300	oC
Temperature coefficient	-40 to +80	-50 to +85	x 10 ⁻⁶ /K
Linearity	< ± 2,5	< ± 1,5	%
Adjustment tolerance	< ± 150	< ± 50	x 10 ⁻⁶
Thermal time constant	typ. 10	3 to 30	s
Type of holder	RW-43	RW-43; RW-80; HC-26/U HC-27/U; TO-39	

For additional details the supplier should be contacted.

			•	
QUARTZ CRYSTA	AL UNITS FOR G	GENERAL FREC	QUENCY ST	ABILIZATION

QUICK REFERENCE DATA

Nominal frequency	21480,000 kHz	
Mode of vibration	fundamental	
Type of holder	RW-80	

APPLICATION

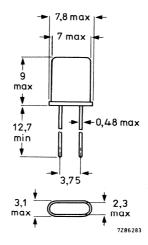
I.F. oscillator in small portable professional radio equipment, e.g. pagers.

DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines



Mass

0,5 g approximately

Marking

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f_L load capacitance 32 pF

21480,000 kHz

Adjustment tolerance

 \pm max. 15 x 10⁻⁶

Tolerance over the temperature range of -5 to +45 °C, with

± max. 15 x 10⁻⁶

respect to + 25 °C Motional capacitance (C₁)

typ. 17,5 fF typ. 4,6 pF

Parallel capacitance (C₀)
Resonance resistance

max. 40 Ω

Pullability $\left(-\frac{\mathrm{d}f}{\mathrm{d}C}\right)$ at f_L

min. $+ 5 \times 10^{-6} \times f_1 / pF$

with load capacitance variation

Maximum permissible d.c. voltage
between terminations

100 V

Operating temperature range

-5 to + 45 °C

TESTS AND REQUIREMENTS

IEC 122	IEC 68-2	test	procedures	requirements
2.5.17	Ва	ageing	1000 h + 100 °C	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
2.5.12 2.5.13	Db	accelerated damp heat	+ 25 to + 55 °C, 6 cycles 95 to 100% R.H.	$\Delta f_r \leqslant 5 \times 10^{-6}$.
2.5.14				$\Delta R \le 20\%$.
	Na	temperature cycling test	-40/+ 125 °C, 10 cycles, 1 h/cycle.	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
2.5.2	Ea	shock	100g sawtooth 6 shocks, 3 directions	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
2.5.3	Fc	vibration	10-500-10 Hz, 10g, 3 h, 3 directions	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
	Tb	resistance to soldering heat	3 s, 350 °C.	≤ 5 x 10 ⁻⁶ . ≤ 20%.
2.5.6	Ub	bending of terminations	1 x 90 ^o , 5 N.	no visible damage.
	Eb	bump	3000 bumps, 30g	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.
	Ed	free fall	3 x 0,75 m on steel	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.

QUICK REFERENCE DATA

Frequency range Mode of vibration

fundamental

3 to 10 MHz

Type of holder

RW-10, RW-33 or RW-36

MECHANICAL DATA

Outlines

See general section "Holders".

Mass

4 q

ELECTRICAL DATA

Adjustment tolerance at + 25 °C

Load capacitance C_L*

Level of drive Motional capacitance C₁

Parallel capacitance C₀

Motional inductance L_1 Resonance resistance R_r

Frequency tolerance with respect

to + 25 °C in temperature range: 0 to + 60 °C

-30 to +80 °C

+ 15 to + 45 °C

Maximum permissible d.c. voltage between terminations

Ageing

 \pm max. 35 x 10^{-6} \pm max. 10 x 10^{-6}

 \pm max. 30 x 10⁻⁶

± 10 x 10⁻⁶

30 pF

0,5 mW

see Fig. 1

see Fig. 1

see Fig. 1

typ. 25 Ω

100 V

within adjustment tolerance

 $^{^{*}}$ Data at other C_L values and for series resonance available on request.

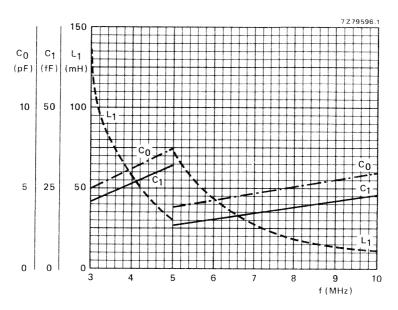


Fig. 1 Typical values for C_0 , C_1 and L_1 as a function of frequency.

TESTS AND REQUIREMENTS

test	IEC-122 clause	IEC-68-2 test method	procedure	requirements
ageing	2.5.17		30 days + 85 °C	$\Delta f/f \leq 10 \times 10^{-6}$
acceleration	2.5.12 2.5.13 2.5.14	Db		$\Delta f/f \le 10 \times 10^{-6}$ R _{ins} > 20 M Ω at 50 V (d.c.)
temperature cycling	-	Na	-20/+ 50 °C, 15 cycles, 1 h/cycle	$\Delta f/f \le 5 \times 10^{-6}$
shock	2.5.2	Ea	100g sawtooth 6 directions, 1 blow/direction	$\Delta f/f \le 5 \times 10^{-6}$ $\Delta R/R < 15\%$
vibration	2.5.3	Fc	10-55-10 Hz 2 hours*	$\Delta f/f \le 5 \times 10^{-6}$ $\Delta R/R < 15\%$
soldering**	2.5.10	Т		no visible damage, terminals well-tinned $\Delta f/f \leqslant 2 \times 10^{-6}$
bending of terminations**	2.5.6	Ub	1 x 90°, 5 N	no visible damage

^{*} The batch is divided into 3 equal parts, each part is tested in 1 of the 3 perpendicular directions.

^{**} Holder RW-10 only.

QUICK REFERENCE DATA

Frequency range 1,8 to 25 MHz
Mode of vibration fundamental
Type of holder RW-33 or RW-36

MECHANICAL DATA

Outlines See general section "Holders".

Mass 4 g

ELECTRICAL DATA

Frequency tolerance in different

temp. ranges with respect to + 25 °C see Table 2

Maximum permissible d.c. voltage

between terminations 100 V

Ageing within adjustment tolerance

TESTS

^{*} Data at other C₁ values and for series resonance available on request.

Table 1 Resonance resistance Rr

frequency MHz	max. R_r
1,800000 — 1,999999	300
2,000000 - 2,249999	250
2,250000 - 3,749999	150
3,750000 - 4,999999	100
5,000000 - 6,999999	50
7,000000 9,999999	30
10,000000 - 25,000000	25

Table 2 Frequency tolerance in different temperature ranges with respect to \pm 25 $^{\rm o}{\rm C}$

frequency temperature	frequency tolerance			
MHz	range range MHz °C	class 0	class I	class II
1,8 - 25	5/+ 45 10/+ 50 15/+ 70	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶
1,8 - 2,3 2,3 - 4 4 - 25	55/+ 105 55/+ 105 55/+ 105	± 30 × 10 ⁻⁶ ± 32,5 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 35 × 10 ⁻⁶ ± 35 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
1,8 - 25	T _{nom} ± 5		± 5 × 10 ⁻⁶	

QUICK REFERENCE DATA

Nominal frequency	6144,000 kHz
Mode of vibration	fundamental
Type of holder	TO-39

APPLICATION

General, e.g. microprocessors.

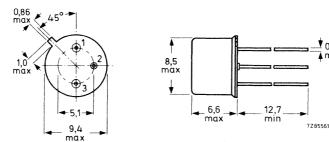
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Pin 2 is connected to the case.



Mass

0,8 g approximately

Marking

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f_L, load capacitance 20 pF

6144,000 kHz

Adjustment tolerance

 \pm max. 25 x 10⁻⁶

Tolerance over the temperature range of -10 to +60 °C, with

± max. 25 x 10⁻⁶

Motional capacitance (C₁)

typ. 7,2 fF

Parallel capacitance (C₀)

respect to + 25 °C

typ. 2,2 pF

Resonance resistance

max. 75 Ω

Pullability $\left(-\frac{df}{dC}\right)$ at f_L

min. $+6 \times 10^{-6} \times f_1 / pF$

with load capacitance variation

Maximum permissible d.c. voltage

100 V

between terminations
Operating temperature range

--10 to +60 °C

TESTS AND REQUIREMENTS

IEC 122	IEC 68-2	test	procedures	requirements
2.5.17	Ва	ageing	1000 h + 100 °C	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
2.5.12 2.5.13	Db	accelerated damp heat	+ 25 to + 55 °C, 6 cycles 95 to 100% R.H.	$\Delta f_r \leqslant 5 \times 10^{-6}$.
2.5.14				$\Delta R \le 20\%$.
AND SOMEON AND SOMEON AND AND AND AND AND AND AND AND AND AN	Na	temperature cycling test	-40/+ 125 °C, 10 cycles, 1 h/cycle.	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
2.5.2	Ea	shock	100g sawtooth 6 shocks, 3 directions	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
2.5.2	Fc	vibration	10-500-10 Hz, 10g, 3 h, 3 directions.	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
	Tb	resistance to soldering heat	3 s, 350 °C.	≤ 5 x 10 ⁻⁶ ≤ 20%.
2.5.6	Ub	bending of terminations	1 × 90°, 5 N	no visible damage.
	Eb	bump	3000 bumps, 30g	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.
	Ed	free fail	3 x 0,75 m on steel	$\Delta f_r \leqslant 5 \times 10^{-6}$. $\Delta R \leqslant 20\%$.

QUICK REFERENCE DATA

Frequency range	1 to 1,8 MHz
Mode of vibration	fundamental
Type of holder	HC-6/U

MECHANICAL DATA

Outlines See general section "Holders".

Mass 4 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	$\pm 20 \times 10^{-6}$
Load capacitance C _L *	30 pF
Level of drive	0,5 mW
Motional capacitance C ₁	5 to 30 fF
Parallel capacitance C ₀	max. 7 pF
Resonance resistance R _r 1,000000 — 1,599999 MHz 1,600000 — 1,799999 MHz	max. $600~\Omega$ max. $300~\Omega$
Frequency tolerance in different temp. ranges with respect to +25 °C	see Table

Maximum permissible d.c. voltage between terminations

Ageing within adjustment tolerance

TESTS

Mechanical and climatic tests according to MIL and IEC procedures

100 V

Table Frequency tolerance in different temperature ranges with respect to + 25 °C.

frequency				
range MHz	range °C	class 0	class I	class II
1 to 1,8	-5/+ 45 10/+ 50 15/+ 70	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶	\pm 7,5 x 10 ⁻⁶ \pm 10 x 10 ⁻⁶ \pm 15 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶
1 to 1,8	-55/+ 105	± 30 × 10 ⁻⁶	± 35 x 10 ⁻⁶	± 40 x 10 ⁻⁶
1 to 1,8	T _{nom} ± 5		± 5 x 10 ⁻⁶	

 $^{^{\}star}$ Data at other C_L values and for series resonance available on request.

QUICK REFERENCE DATA

Nominal frequency 1000,000 kHz
Mode of vibration fundamental
Type of holder HC-6/U

MECHANICAL DATA

Outlines: see general section "Holders"

Mass: 4 g approximately

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f_L ,

load capacitance 30 pF 1000,000 kHz

Adjustment tolerance \pm max. 20 x 10⁻⁶

Tolerance over the temperature range of

 $-20 \text{ to } +70 \,^{\circ}\text{C}$, with respect to $+25 \,^{\circ}\text{C}$ \pm max. 30×10^{-6}

Motional capacitance C₁ typ. 9 fF

Parallel capacitance C₀ typ. 3,5 pF

Resonance resistance R_r max. 600 Ω

Pullability $-\frac{df}{dC}$ at f_L

with load capacitance variation min. $\pm 4 \times 10^{-6} \times f_L/pF$

Maximum permissible d.c. voltage

between terminations 100 V

Operating temperature range $-20 \text{ to } +70 \text{ }^{\circ}\text{C}$

Marking

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

QUICK REFERENCE DATA

Frequency range 1.8 to 25 MHz Mode of vibration fundamental

Type of holder

1,8 to 2,3 MHz HC-27/U, extended (26 mm) 2,4 to 25 MHz HC-27/U

MECHANICAL DATA

Outlines See general section "Holders".

Mass 2,5 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C $\pm 10 \times 10^{-6}$ Load capacitance C₁ * 30 pF Level of drive 0.5 mW

Motional capacitance C₁ see Figs 1 to 4

Parallel capacitance Co. max. 7 pF, see also Fig. 1

Motional inductance L₁ see Figs 1 to 4

Resonance resistance Rr see Table 1

Frequency tolerance in different temperature

ranges with respect to + 25 °C see Table 2

Maximum permissible d.c. voltage between terminations 100 V

Ageing after 90 days non-operative

at + 85 ± 2 °C $(-0.5 \text{ to} + 1) \times 10^{-6}$

TESTS

^{*} Data at other C_L values and for series resonance available on request.

Table 1 Resonance resistance Rr

frequency MHz		max. R_r
1,800000 —	1,869999	220
1,870000 -	1,999999	185
2,000000	2,119999	165
2,120000 -	2,249999	150
2,250000 -	2,599999	125
2,600000	2,999999	90
3,000000	3,399999	70
3,400000	3,749999	52
3,750000	3,999999	45
4,000000	4,999999	37
5,000000	6,999999	25
7,000000 —	9,999999	20
10,000000 —	14,999999	18
15,000000 —	25,000000	15

Table 2, Frequency tolerance in different temperature ranges with respect to + 25 °C

frequency	temperature	frequency tolerance		
range MHz	range range MHz ^o C	class 0	class I	class II
1,8 to 25	-5/+ 45 -10/+ 50 -15/+ 70	$\begin{array}{cccc} \pm & 5 & \times 10^{-6} \\ \pm & 7.5 \times 10^{-6} \\ \pm & 10 & \times 10^{-6} \end{array}$	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶
1,8 to 2,3 2,3 to 7 7 to 25	-55/+ 105 -55/+ 105 -55/+ 105	± 30 × 10 ⁻⁶ ± 32,5 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 35 × 10 ⁻⁶ ± 35 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
1,8 to 25	T _{nom} ± 5		± 2,5 × 10 ⁻⁶	± 5 x 10 ⁻⁶

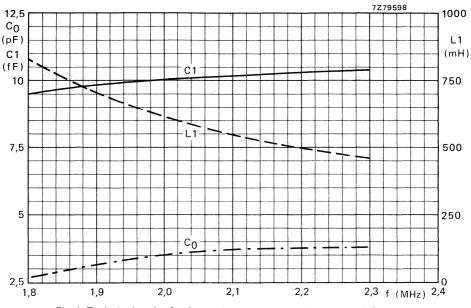


Fig. 1 Typical values for C_0 , C_1 and L_1 for frequencies from 1,8 to 2,3 MHz.

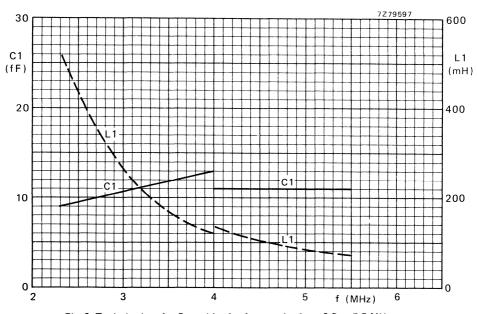


Fig. 2 Typical values for C_1 and L_1 for frequencies from 2,3 to 5,5 MHz.

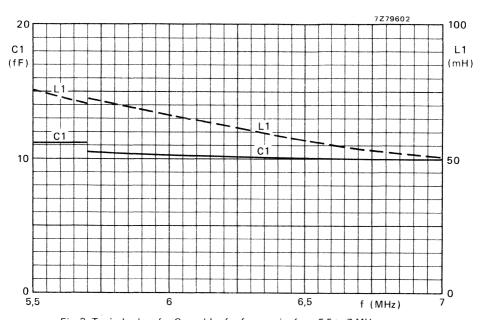


Fig. 3 Typical values for C_1 and L_1 for frequencies from 5,5 to 7 MHz.

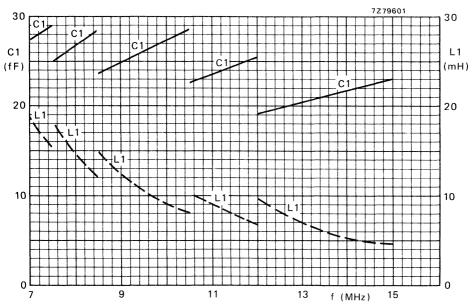


Fig. 4 Typical values for C_1 and L_1 for frequencies from 7 to 15 MHz.

QUICK REFERENCE DATA

Frequency range Mode of vibration 4,5 to 25 MHz fundamental

Type of holder

HC-26/U or HC-29/U

MECHANICAL DATA

Outlines

See general section "Holders".

Mass

0,8 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C

Load capacitance Cu *

± 10 x 10⁻⁶

Load capacitance C_L*

30 pF

Level of drive

0,5 mW

Motional capacitance C₁

Parallel capacitance C₀

Motional inductance L₁

see Figs 1 and 2

Resonance resistance R_r

see Table 1

Frequency tolerance in different temperature

see Table 2

ranges with respect to + 25 °C

Maximum permissible d.c. voltage between terminations

terminations 100 V

Ageing after 90 days non-operative at $+85 \pm 2$ °C

 $(-0.5 \text{ to} + 1) \times 10^{-6}$

TESTS

^{*} Data at other C₁ values and for series resonance available on request.

Table 1 Resonance resistance R_r

frequency	max. R _r
MHz	Ω
4,500000 - 4,749999	110
4,750000 - 5,999999	70
6,000000 - 6,9 99999 9	45
7,000000 - 9,999999	30
10,000000 - 14,999999	25
15,000000 - 25,000000	20

 Table 2 Frequency tolerance in different temperature ranges with respect to + 25 °C

frequency	temperature	frequency tolerance		
range MHz	oC range	class 0	class I	class II
4,5 to 25	5/+ 45 10/+ 50 15/+ 70	$ \pm $ 5 x 10 ⁻⁶ $ \pm $ 7,5 x 10 ⁻⁶ $ \pm $ 10 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶	$\pm 10 \times 10^{-6}$ $\pm 15 \times 10^{-6}$ $\pm 20 \times 10^{-6}$
4,5 to 6 6 to 12 12 to 25	-55/+ 105 -55/+ 105 -55/+ 105	± 30 × 10 ⁻⁶ ± 32,5 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 40 × 10 ⁻⁶ ± 35 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 50 × 10 ⁻⁶ ± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
4,5 to 25	T _{nom} ±5		± 2,5 × 10 ⁻⁶	± 5 × 10 ⁻⁶

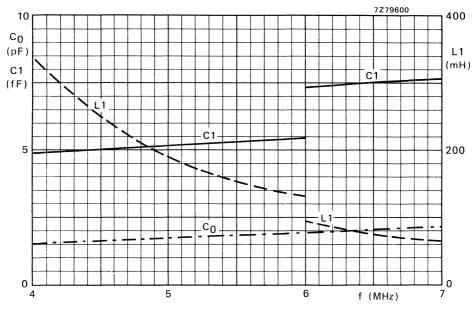


Fig. 1 Typical values of L_1 , C_0 and C_1 for frequencies from 4 to 7 MHz.

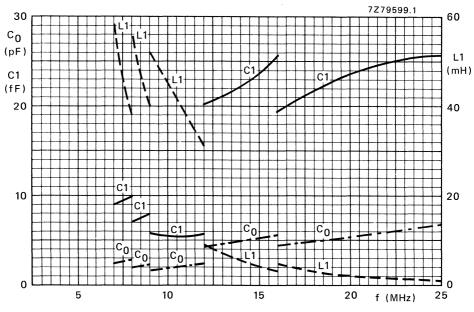


Fig. 2 Typical values of L_1 , C_0 and C_1 for frequencies from 7 to 25 MHz.

QUICK REFERENCE DATA

Frequency range	4,5 to 25 MHz
Mode of vibration	fundamental
Type of holder	RW-42 or RW-43

MECHANICAL DATA

Outlines See general section "Holders".

Mass 1 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	$\pm 10 \times 10^{-6}$
Load capacitance C _L *	30 pF
Level of drive	0,5 mW
Motional capacitance C ₁	5 to 30 fF
Parallel capacitance C ₀	max. 7 pF

Resonance resistance R_r

Frequency tolerance in different temperature

ranges with respect to + 25 °C see Table

Maximum permissible d.c. voltage between terminations

Ageing within adjustment tolerance

100 V

TESTS

Mechanical and climatic tests according to MIL and IEC procedures.

Table Frequency tolerance in different temperature ranges with respect to + 25 °C.

temperature	frequency tolerance		
oC range	class 0	class I	class II
-5/+ 45 -10/+ 50 -15/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom.} ± 5		± 5 x 10 ⁻⁶	

^{*} Data at other C_L values and for series resonance available on request.

QUICK REFERENCE DATA

Frequency range	10 to 75 MHz
Mode of vibration	third overtone
Type of holder	HC-27/U

MECHANICAL DATA

Outlines See general section "Holders".

Mass 2,5 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	$\pm 10 \times 10^{-6}$
Level of drive	0,5 mW
Motional capacitance C ₁	typ. 1,5 fF
Parallel capacitance C ₀	max.7 pF
Resonance resistance R _r	max.40 Ω
Frequency tolerance in different temperature ranges with respect to +25 °C	see Table
Maximum permissible d.c. voltage between terminations	100 V

Ageing after 90 days non-operative at $+85 \pm 2$ °C

 $(-0.5 \text{ to } + 1) \times 10^{-6}$

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature frequency tolera		frequency tolerance	
range oC	class 0	class I	class II
-5/+50 -10/+60 -20/+70 -55/+105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 x 10 ⁻⁶

QUICK REFERENCE DATA

Nominal frequency 10,00000 MHz

Mode of vibration third overtone

Type of holder all-glass, HC-27/U

MECHANICAL DATA

Outlines See general section "Holders"

Mass 2,5 g approximately

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of +25 ± 2 °C and a level of drive of 1 mA.*

Load resonance frequency fL,

Motional inductance (L₁)

load capacitance 75 pF**

10,000 00 MHz

Adjustment tolerance

± max. 5 x 10⁻⁶

Tolerance over the temperature range of +69 to +71 °C,

 $\begin{array}{lll} \text{with respect to +70 °C} & \pm \max. \ 3 \times 10^{-7} \\ \text{Motional capacitance (C_1)} & \text{typ. 2,1 fF} \\ \text{Parallel capacitance (C_0)} & \text{typ. 5 pF} \\ \end{array}$

Resonance resistance over the temperature range of

-40 to +75 $^{\rm O}{\rm C}$ max. 40 Ω Maximum permissible d.c. voltage between terminations 100 V

Ageing $\pm 5 \times 10^{-8} / \text{month}$

Operating temperature range —40 to +75 °C

Stability of oscillator frequency. This depends on the crystal oven used. Stability figures of 1×10^{-6} to 1×10^{-7} can be achieved.

TESTS AND REQUIREMENTS

According to MIL-C-3098C. $\Delta f/f$ \pm max. 3 x 10⁻⁶ $\Delta R/R$ \pm max. 15%

Marking

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit is provided with pins for socket mounting.

- * Influence of drive level on frequency is max. 2 x 10⁻⁸/dB.
- ** Data at other C₁ and for series resonance available on request.

typ. 120 mH

QUICK REFERENCE DATA

Frequency range	20 to 75 MHz
Mode of vibration	third overtone
Type of holder	HC-26/U or HC-29/U

MECHANICAL DATA

Outlines See general section "Holders".

Mass 0,8 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	$\pm 10 \times 10^{-6}$
Level of drive	0,5 mW
Motional capacitance C ₁	typ. 1,5 fF
Parallel capacitance C ₀	max. 7 pF
Resonance resistance R _r	max. 30 Ω
Frequency tolerance in different temperature ranges with respect to + 25 °C	see Table
Maximum permissible d.c. voltage between terminations	100 V
Ageing after 90 days non-operative at $+85 \pm 2$ °C	$(-0.5 \text{ to} + 1) \times 10^{-6}$

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance		
oC Laude	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 x 10 ⁻⁶

QUICK REFERENCE DATA

Frequency range 17 to 75 MHz
Mode of vibration third overtone
Type of holder RW-42 or RW-43

MECHANICAL DATA

Outlines See general section "Holders".

Mass 1

ELECTRICAL DATA

Adjustment tolerance at + 25 °C \pm 10 x 10⁻⁶ Level of drive 0,5 mW Motional capacitance C₁ typ. 1,5 fF Parallel capacitance C₀ max. 7 pF Resonance resistance R_r max. 40 Ω Frequency tolerance in different temperature ranges with respect to + 25 °C see Table

Maximum permissible d.c. voltage

between terminations

Ageing within adjustment tolerance

100 V

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance		
range °C	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 5 × 10 ⁻⁶	

QUICK REFERENCE DATA

Frequency range 10 to 75 MHz

Mode of vibration third overtone

Type of holder RW-33 or RW-36

MECHANICAL DATA

Outlines See general section "Holders".

Mass 4 q

ELECTRICAL DATA

Adjustment tolerance at + 25 °C \pm 10 x 10-6 Level of drive 0,5 mW Motional capacitance C₁ typ. 1,5 fF Parallel capacitance C₀ max. 7 pF Resonance resistance R_r max. 60 Ω Frequency tolerance in different temperature

ranges with respect to + 25 °C

Maximum permissible d.c. voltage

between terminations

Ageing within adjustment tolerance

see Table

100 V

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance		
oC range	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
T _{nom} ± 5		± 5 x 10 ⁻⁶	

QUICK REFERENCE DATA

Frequency range 50 to 125 MHz
Mode of vibration fifth overtone
Type of holder HC-27/U

MECHANICAL DATA

Outlines See general section "Holders".

Mass 2,5 q

ELECTRICAL DATA

 $\begin{array}{lll} \mbox{Adjustment tolerance at + 25 °C} & \pm 10 \times 10^{-6} \\ \mbox{Level of drive} & 0,5 \mbox{ mW} \\ \mbox{Motional capacitance C_1} & \mbox{typ. 0,5 fF} \\ \mbox{Parallel capacitance C_0} & \mbox{max. 7 pF} \\ \mbox{Resonance resistance R_r} & \mbox{max. 50 } \Omega \end{array}$

Frequency tolerance in different temperature ranges

with respect to + 25 °C see Table

Maximum permissible d.c. voltage

between terminations 100 V

Ageing after 90 days non-operative

at +85 ± 2 $^{\circ}$ C (-0,5 to +1) × 10⁻⁶

TESTS

Mechanical and climatic tests according to MIL and IEC procedures.

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance		
oC range	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 x 10 ⁻⁶

QUICK REFERENCE DATA

Frequency range 50 to 125 MHz
Mode of vibration fifth overtone
Type of holder HC-26/U or HC-29/U

MECHANICAL DATA

Outlines See general section "Holders".

Mass 0.8 a

ELECTRICAL DATA

Adjustment tolerance at + 25 °C $\pm 10 \times 10^{-6}$ Level of drive 0.5 mW Motional capacitance C₁ typ. 0,5 fF Parallel capacitance Co. max. 7 pF Resonance resistance Rr 50 to 90 MHz max. 50 Ω 90 to 125 MHz max. 70 Ω Frequency tolerance in different temperature ranges with respect to + 25 °C see Table

Maximum permissible d.c. voltage

between terminations 100 V Ageing after 90 days non-operative

at + 85 ± 2 °C (-0,5 to + 1) x 10^{-6}

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance		
oC range	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 × 10 ⁻⁶

QUARTZ CRYSTAL UNITS

QUICK REFERENCE DATA

Frequency range 50 to 125 MHz
Mode of vibration fifth overtone
Type of holder RW-42 or RW-43

MECHANICAL DATA

Outlines See general section "Holders".

Mass 1 c

ELECTRICAL DATA

 $\begin{array}{lll} \mbox{Adjustment tolerance at } + 25 \mbox{ }^{O}\mbox{C} & \pm 10 \times 10^{-6} \\ \mbox{Level of drive} & 0.5 \mbox{ mW} \\ \mbox{Motional capacitance C}_1 & \mbox{typ. 0,5 fF} \\ \mbox{Parallel capacitance C}_0 & \mbox{max. 7 pF} \\ \end{array}$

Resonance resistance R_r

50 to 90 MHz $$\rm max.~60~\Omega$$ 90 to 125 MHz $$\rm max.~80~\Omega$$

Frequency tolerance in different temperature

ranges with respect to + 25 °C see Table

Maximum permissible d.c. voltage between terminations

Ageing within adjustment tolerance

TESTS

Mechanical and climatic tests according to MIL and IEC procedures.

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance			
°C °C	class 0	class I	class II	
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶	
T _{nom} ± 5		± 5 x 10 ⁻⁶		

100 V

QUARTZ CRYSTAL UNITS

QUICK REFERENCE DATA

Frequency range 50 to 125 MHz
Mode of vibration fifth overtone
Type of holder RW-33 or RW-36

MECHANICAL DATA

Outlines See general section "Holders".

Mass 4 q

ELECTRICAL DATA

Adjustment tolerance at + 25 °C \pm 10 x 10⁻⁶ Level of drive 0,5 mW Motional capacitance C₁ typ. 0,5 fF Parallel capacitance C₀ max. 7 pF Resonance resistance R_r 20 to 100 Ω

Frequency tolerance in different temperature ranges

with respect to + 25 °C see Table

Maximum permissible d.c. voltage

between terminations 100 V

Ageing within the adjustment tolerance

TESTS

Mechanical and climatic tests according to MIL and IEC procedures.

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance			
oC range	class 0	class I	class II	
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶	
T _{nom} ± 5		± 5 × 10 ⁻⁶		

TEMPERATUR	E COMPENSATED	CRYSTAL OSCILLA	TORS

TEMPERATURE COMPENSATED CRYSTAL OSCILLATORS

TYPE SELECTION

frequency range MHz	temperature range oC	frequency tolerance x 10 ⁻⁶	supply voltage	adjustment facility	catalogue number	page
4 to 15	0 to + 50 -10 to + 60 -20 to + 70	± 1 ± 1,5 ± 2	20 20 20	none	4322 190 2 4322 190 1 4322 190 0	67
4,5 to 15	0 to + 50 -10 to + 60 -20 to + 70	± 1 ± 1,5 ± 2	20 20 20	external variable capacitor	4322 191 2 4322 191 1 4322 191 0	71
4,5 to 15	0 to + 50 10 to + 60 20 to + 70	± 1 ± 1,5 ± 2	20 20 20	external variable resistor	4322 192 2 4322 192 1 4322 192 0	75
20 to 50	0 to + 50 -20 to + 70 0 to + 50 -20 to + 70	± 1 ± 2 ± 2 ± 3	2 2 10 10	external variable capacitor	4322 195 0 4322 195 1 4322 195 2 4322 195 3	79

TEMPERATURE COMPENSATED CRYSTAL OSCILLATOR

QUICK REFERENCE DATA

Catalogue numbers	4322 190 0	4322 190 1	4322 190 2	
Frequency range	4,5 to 15*	4,5 to 15	45 to 15	MHz
Frequency tolerance	$\pm 2 \times 10^{-6}$	± 1,5 x 10 ⁻⁶	± 1 x 10 ⁻⁶	
Temperature range	-20 to + 70	-10 to +60	0 to + 50	°C
Supply voltage	+ 12	+ 12	+ 12	V

APPLICATION

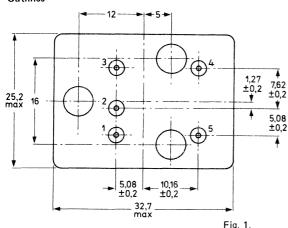
Temperature compensated crystal oscillators (TCXOs) are used in mobilophones, electronic timing devices, measuring equipment, synthesizers, etc.

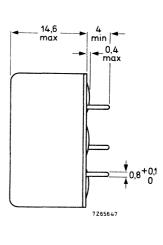
DESCRIPTION

A TCXO module comprises a quartz crystal oscillator, and a thermally controlled circuit that compensates for frequency changes over the whole temperature range. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with 5 connecting pins which are arranged to fit printed-wiring boards with a grid pitch of 2,54 mm (see Fig. 1).

MECHANICAL DATA







* Complete 12-digit catalogue numbers have been fixed for TCXOs for the following frequencies:

5 MHz : 4322 190 00011 10 MHz : 4322 190 00001

Catalogue numbers for TCXOs with other frequencies will be fixed upon request.

4322 190 SERIES

Mass

25 g approximately

Marking

The units are provided with a label showing the following information:

тсхо	Type 4322 190
Frequency Δf 25 °C Range No.	MHz Hz oC

ELECTRICAL DATA

Supply voltage, V_s + 12 V \pm 10% via R_1 = 470 Ω (see Fig. 2)

 $+ 12 \text{ V} \pm 20\% \text{ via R}_1 = 330 \Omega$

Power consumption max. 200 mW Frequency range 4,5 - 15 MHz

Frequency tolerance/temperature range

at specified V_s , Z_L , and

at a temp. rate of max. 1 K/min.

Ageing $\pm 1 \times 10^{-6}$ per year

Correction on aging influence by connecting pin 3 to pin 2 $-2 + 1 - 2 \times 10^{-6}$

Internal resistance, R $_{i}$ 2800 Ω \pm 5%

 $\label{eq:continuous} \begin{array}{ll} \text{Internal capacitance, C_i} & 5.5 \text{ pF} \pm 5\% \\ \text{Internal voltage source, V_i} & 600 \text{ mV} \pm 40\% \\ \end{array}$

Load impedance, Z $_{\rm L}$ $\,$ min. 500 Ω $\,$ Output voltage, V $_{\rm O}$ $\,$ see Figs 3 and 4

Storage temperature range —25 to +85 °C

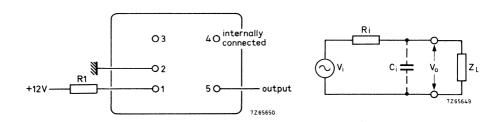


Fig. 2 Connection diagram.

Fig. 3 Equivalent circuit.

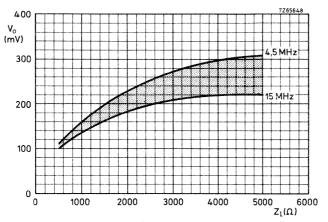


Fig. 4 Output voltage as a function of load impedance (typical values).

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f$ max. 5 x 10 ⁻⁷
Fc	vibration	10 to 500 Hz, 10g, in 3 directions, 30 min per direction	Δ f/f max. 5 x 10 ⁻⁷
Tb	resistance to soldering heat	260 ± 5 °C, 10 ± 1 s	Δ f/f max. 5 x 10 ⁻⁷
Db	climatic		Δ f/f max. 5 x 10 ⁻⁷

Note

Other specifications for TCXOs with respect to temperature range and for frequency tolerance can be made avilable on request.



TEMPERATURE COMPENSATED CRYSTAL OSCILLATOR

QUICK REFERENCE DATA

Catalogue numbers	4322 191 0	4322 191 1	4322 191 2	
Frequency range	4,5 to 15*	4,5 to 15	45 to 15	MHz
Frequency tolerance	$\pm 2 \times 10^{-6}$	± 1,5 x 10 ⁻⁶	± 1 x 10 ⁻⁶	
Temperature range	20 to + 70	-10 to +60	0 to + 50	oC
Supply voltage	+ 12	+ 12	+ 12	V
Frequency is adjustable by external va	ariable capacitor			

APPLICATION

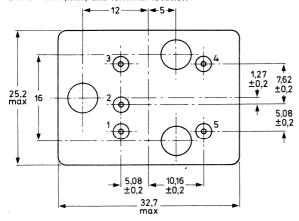
Temperature compensated crystal oscillators (TCXOs) are used in mobilophones, electronic timing devices, measuring equipment, synthesizers, etc.

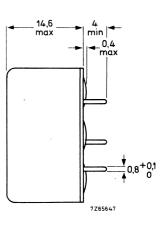
DESCRIPTION

A TCXO module comprises a quartz crystal oscillator, and a thermally controlled circuit that compensates for frequency changes over the whole temperature range. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with 5 connecting pins which are arranged to fit printed-wiring boards with a grid pitch of 2,54 mm (see Fig. 1).

MECHANICAL DATA

Dimensions (mm) and terminal location





* Complete 12-digit catalogue numbers have been fixed for TCXOs for the following frequencies:

March 1984

4322 191 SERIES

Mass

25 g approximately

Marking

The units are provided with a label showing the following information:

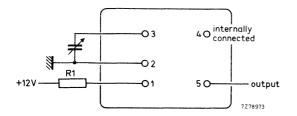
тсхо	Type 4322 191
Frequency Δf 25 °C Range No.	MHz Hz OC

ELECTRICAL DATA

+ 12 V \pm 10% via R $_1$ = 470 Ω (see Fig. 2) + 12 V \pm 20% via R $_1$ = 330 Ω
max. 200 mW
4,5 — 15 MHz
± 2 × 10 ⁻⁶ ± 1,5 × 10 ⁻⁶ ± 1 × 10 ⁻⁶
\pm 1 x 10 ⁻⁶ per year
$\pm 2 \times 10^{-6}$ (see note below)
2800 Ω ± 5%
5,5 pF ± 5%
600 mV ± 40%
min. 500 Ω
see Figs 3 and 4
–25 to + 85 °C

Note

It is not guaranteed that the nominal frequency occurs at room temperature. The nominal frequency can be shifted by connecting a variable capacitor of max. 60 pF externally between pin 2 and 3. For optimum stability over the whole temperature range the oscillator should be adjusted at room temperature to a frequency which deviates from the nominal one by an amount mentioned as " Δf 25 °C ... Hz" on the label on the module. After this adjustment a trimming range of \pm min. 2 x 10⁻⁶ is still available to correct ageing influences.



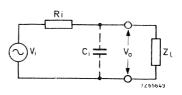


Fig. 2 Connection diagram.

Fig. 3 Equivalent circuit.

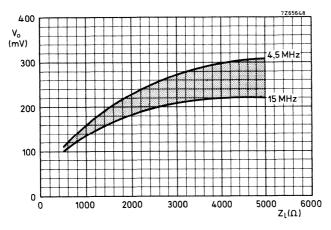


Fig. 4 Output voltage as a function of load impedance (typical values).

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f$ max. 5 x 10^{-7}
Fc	vibration	10 to 500 Hz, 10g, in 3 directions 30 min per direction	Δ f/f max. 5 x 10 ⁻⁷
Tb	resistance to soldering heat	260 ± 5 °C, 10 ± 1 s	Δ f/f max. 5 x 10 ⁻⁷
Db	climatic		$\Delta f/f$ max. 5 x 10^{-7}

Note

Other specifications for TCXOs with respect to temperature range and for frequency tolerance can be made available on request.



TEMPERATURE COMPENSATED CRYSTAL OSCILLATOR

QUICK REFERENCE DATA

Catalogue numbers	4322 192 0	4322 192 1	4322 192 2	
Frequency range	4,5 to 15*	4,5 to 15	45 to 15	MHz
Frequency tolerance	$\pm 2 \times 10^{-6}$	± 1,5 x 10 ⁻⁶	± 1 × 10 ⁻⁶	
Temperature range	-20 to + 70	-10 to +60	0 to +50	oC
Supply voltage	+ 12	+12	+ 12	V
Frequency is adjustable by extending	ernal variable resistor	1 .	L	

APPLICATION

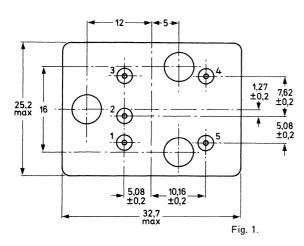
Temperature compensated crystal oscillators (TCXOs) are used in mobilophones, electronic timing devices, measuring equipment, synthesizers, etc.

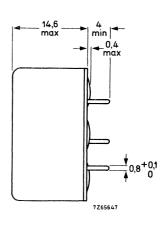
DESCRIPTION

A TCXO module comprises a quartz crystal oscillator, and a thermally controlled circuit that compensates for frequency changes over the whole temperature range. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with 5 connecting pins which are arranged to fit printed-wiring boards with a grid pitch of 2,54 mm (see Fig. 1).

MECHANICAL DATA

Outlines





^{*} Complete 12-digit catalogue number has been fixed for TCXOs for the following frequencies.

10 MHz: 4322 192 00001

Catalogue numbers for TCXOs with other frequencies will be fixed upon request.

4322 192 SERIES

Mass

25 g approximately

Marking

The units are provided with a label showing the following information:

TCXO	Type 4322 192
Frequency Δf 25 ^O C Range No.	oC Hz WHz

ELECTRICAL DATA

Supply voltage, V _s	+ 12 V \pm 10% via R ₁ = 470 Ω (see Fig. 2) + 12 V \pm 20% via R ₁ = 330 Ω
Power consumption	max. 200 mW
Frequency range	4,5 — 15 MHz

Frequency tolerance/temperature range after adjustment (see note), at specified V_s , Z_L , and at a temperature rate of max. 1 K/min. cat. numbers 4322 192 0 -20 to $+70^\circ$

cat. numbers 4322 192 0 -20 to $+70^{\circ}$ cat. numbers 4322 192 1 -10 to $+60^{\circ}$ cat. numbers 4322 192 2 0 to 50° \pm 1,5 x 10^{-6} cat. \pm 1 x \pm 10⁻⁶ per year

Correction on ageing influence \pm 2 x 10⁻⁶ (see note below) Internal resistance, R_j 2800 Ω \pm 5%

 $\begin{array}{ll} \text{Internal capacitance, C}_{i} & 5.5 \text{ pF} \pm 5\% \\ \\ \text{Internal voltage source, V}_{i} & 600 \text{ mV} \pm 40\% \\ \\ \text{Load impedance, Z}_{L} & \text{min. 500 } \Omega \\ \\ \text{Output voltage, V}_{O} & \text{see Figs 3 and 4} \\ \end{array}$

Output voltage, V_0 see Figs 3 and 4 Storage temperature range $-25 \text{ to } +85 \text{ }^{\circ}\text{C}$

Note

It is not guaranteed that the nominal frequency occurs at room temperature. The nominal frequency can be shifted by connecting a variable resistor of 2 k Ω externally between pin 2 and 3. For optimum stability over the whole temperature range the oscillator should be adjusted at room temperature to a frequency which deviates from the nominal one by an amount mentioned as " Δf 25 °C ... Hz" on the label on the module. After this adjustment a trimming range of \pm min. 2 x 10⁻⁶ is still available to correct ageing influences.

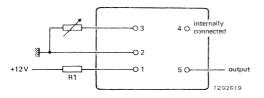


Fig. 2 Connection diagram.

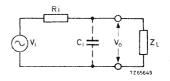


Fig. 3 Equivalent circuit.

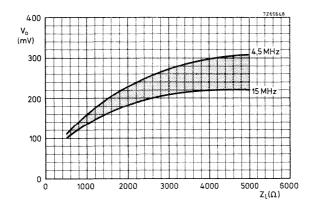


Fig. 4 Output voltage as a function of load impedance (typical values).

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f$ max. 5 x 10 ⁻⁷
F	vibration	10 to 500 Hz, 10g, in 3 directions 30 min per direction	$\Delta f/f$ max. 5×10^{-7}
Т	soldering		
D	climatic		$\Delta f/f$ max. 5 x 10^{-7}

Note

Other specifications for TCXOs with respect to temperature range and for frequency tolerance can be made available on request.



TEMPERATURE COMPENSATED CRYSTAL OSCILLATOR

QUICK REFERENCE DATA

Catalogue numbers	4322 195 0	4322 195 1	4322 195 2	4322 195 3	-
Frequency range	20 to 50	20 to 50	20 to 50	20 to 50	MHz
Frequency tolerance	$\pm 1 \times 10^{-6}$	± 2 x 10 ⁻⁶	± 2 x 10 ⁻⁶	± 3 x 10 ⁻⁶	
Temperature range	0 to + 50	-20 to + 70	0 to + 50	20 to + 70	oC
Supply voltage	12 V ± 2%	12 V ± 2%	12 V ± 10%	12 V ± 10%	
Frequency is adjustable by external variable capacitor					

APPLICATION

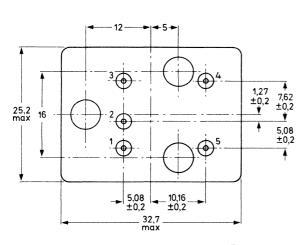
Temperature compensated crystal oscillators (TCXOs) are used in mobilophones, electronic timing devices, measuring equipment, synthesizers, etc.

DESCRIPTION

A TCXO module comprises a quartz crystal oscillator, and a thermally controlled circuit that compensates for frequency changes over the whole temperature range. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with 5 connecting pins which are arranged to fit printed-wiring boards with a grid pitch of 2,54 mm (see Fig. 1).

MECHANICAL DATA

Outlines



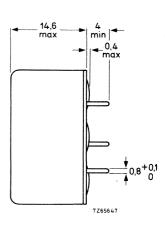


Fig. 1.

4322 195 SERIES

Mass

25 g approximately

Marking

The units are provided with a label showing the following information:

тсхо	Type 4322 195
Frequency Δf 25 °C Range No.	MHz Hz OC

ELECTRICAL DATA

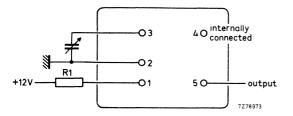
Supply voltage, V _s , see Fig. 2 cat. numbers 4322 195 0 and 4322 195 1 cat. numbers 4322 195 2 and 4322 195 3	+ 12 V ± max. 2% + 12 V ± max. 10%
Power consumption	typ. 160 mW, max. 180 mW
Frequency range	20 to 50 MHz
Frequency tolerance/temperature range after adjustment (see note), at specified V_s , Z_L , and at a temperature rate of 1 K/min cat. numbers 4322 195 0 0 to +50 °C cat. numbers 4322 195 120 to +70 °C cat. numbers 4322 195 2 0 to 50 °C cat. numbers 4322 195 320 to +70 °C	see also Fig. 4 ± 1 x 10 ⁻⁶ ± 2 x 10 ⁻⁶ ± 2 x 10 ⁻⁶ ± 3 x 10 ⁻⁶
Ageing	± 1 x 10 ⁻⁶ per year
Correction on ageing influence	$\pm > 2 \times 10^{-6}$, see note
Internal resistance, R _i	2800 Ω ± 5%
Internal capacitance, Ci	5,5 pF ± 5%
Internal voltage source, V _i	600 mV ± 40%
Load impedance, Z _L	min. 500 Ω
Output voltage, V _O	see Fig. 5

Note

It is not guaranteed that the nominal frequency occurs at room temperature. The nominal frequency can be shifted by connecting a variable capacitor of max. 20 pF externally between pins 2 and 3. For optimum stability over the whole temperature range the oscillator should be adjusted at room temperature to a frequency which deviates from the nominal one by an amount mentioned as " $\Delta f 25$ °C . . . Hz" on the label on the module. After this adjustment a trimming range of \pm min. 2 x 10^{-6} is still available to correct aging influences.

 $-25 \text{ to} + 85 \,^{\circ}\text{C}$

Storage temperature range



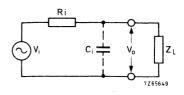


Fig. 2 Connection diagram. R1 = 390 Ω

Fig. 3 Equivalent circuit.

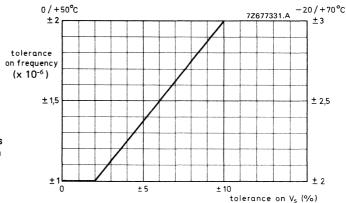


Fig. 4 Frequency tolerance as a function of the tolerance on supply voltage.

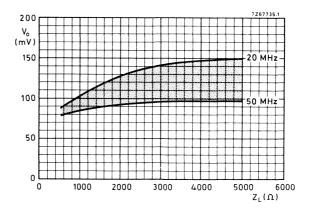


Fig. 5 Output voltage as a function of load impedance (typical values).

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f$ max. 5×10^{-7}
Fc	vibration	10 to 500 Hz, 10g, in 3 directions, 30 min per direction	$\Delta f/f$ max. 5 x 10^{-7}
Tb	resistance soldering heat	260 ± 5 °C, 10 ± 1 s	$\Delta f/f$ max. 5 x 10 ⁻⁷
Db	climatic		$\Delta f/f$ max. 5×10^{-7}

Note

Other TCXO specifications concerning supply voltage, temperature range and frequency tolerance can be made available on request.

SERIES

DEVELOPMENT SAMPLE DATA

This information is derived from development samples made available for evaluation. It does not necessarily imply that the device will go into remilar production.

DIGITAL TEMPERATURE COMPENSATED OSCILLATOR (DTCXO)

QUICK REFERENCE DATA

Frequency range	4,5 to 15 MHz
Stability	$\leq \pm 5 \times 10^{-7}$
Supply voltage	5 V ± 5%
Output	10 x LPS TTL (2 x TTL)

APPLICATION

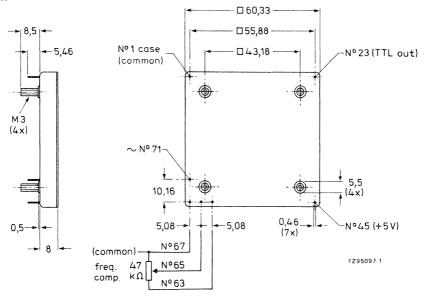
DTCXOs are used in communication and measuring equipment for which a very high stability is required at low power consumption.

DESCRIPTION

A DTCXO comprises a quartz crystal oscillator, a quartz crystal temperature measuring device together with an electronic compensation network which is digitally controlled.

MECHANICAL DATA

Outlines



Mass: $\approx 70 \text{ g}$

4322 198 SERIFS

Marking

The frequency in MHz, the stability, the temperature range, the catalogue number, date code (month/year) and the connecting circuit are printed on a label which is stuck to the holder.

Mounting

The unit can be mounted on a printed circuit board and/or secured by 4 bolts M3.

ELECTRICAL DATA

Frequency range 4,5 to 15 MHz Stability $\leq \pm 5 \times 10^{-7}$ Temperature range $-40 \text{ to } +85 \text{ }^{\circ}\text{C}$

Storage temperature range —55 to +125 °C

Ageing \leq 1,5 x 10⁻⁶ during 10 years at 85 °C

adjustable by an external resistor of 47 $k\Omega$

Supply voltage $5 \text{ V} \pm 5\%$

Supply current max. 25 mA; typ. 20 mA
Output 10 x LPS TTL, (2 x TTL)

Duty cycle 40 to 60% Stability versus supply variation $\leq 1.10^{-7}$

Time to reach a stability within

 $\pm 5 \times 10^{-7}$ at switch on < 1 s

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f$ max. 2 x 10^{-7}
Fc	vibration	10 to 500 Hz, 10g, in 3 directions, 30 min per direction	$\Delta f/f$ max. 2 x 10 ⁻⁷
Tb	resistance to soldering heat	260 ± 5 °C, 10 ± 1 s	$\Delta f/f$ max. 2 x 10 ⁻⁷
Db	climatic		Δ f/f max. 2 x 10 ⁻⁷





COMPACT INTEGRATED OSCILLATORS

QUICK REFERENCE DATA

Frequency range	1,0 to 20 MHz
Frequency tolerance, all effects included	± 100 x 10 ⁻⁶
Operating temperature range	0 to + 70 °C
Supply voltage	5 V ± 10%
Load	up to 10 standard TTL

APPLICATION

Due to their small size and hermetical sealing the oscillators can be supplied in microprocessors, measuring equipment, medical equipment, electronic timing devices, etc.

DESCRIPTION

A compact integrated oscillator comprises a quartz crystal and a thin film hybrid oscillator circuit. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with four connecting pins having a spacing compatible with 14-pin DIL packages.

MECHANICAL DATA

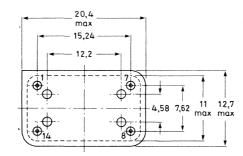
Outlines

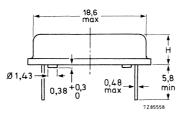
pin 1 = not connected, can be made available for cable input on special request.

pin 7 = ground, 0 V*

pin 8 = output

pin 14 = supply, +5 V





H = 4.9 mm.

^{*} The case can be connected to pin 7 for shielding, on special request.

4322 199 SERIES

Marking

The units are marked as follows:

- frequency in kHz
- last five digits of catalogue number
- code for month and year of manufacture

Mounting

Soldering conditions

max. 260 °C, max. 10 s

 $\pm 100 \times 10^{-6}$

ELECTRICAL DATA

Supply voltage	V _{CC}	+ 5 V ± 10%
Supply current 1 to 4 MHz 4 to 20 MHz	lcc lcc	typ. 30 mA; max. 55 mA typ. 14 mA; max. 25 mA
Frequency range		1,0 to 20 MHz

Frequency tolerance
This tolerance includes:

Initial calibration tolerance at 25 °C; change in operating temperature (0 to + 70 °C); change in supply voltage; change in load; change in environmental conditions and ageing.

Output characteristics

low level	voltage (V _{CC} = 4,5 V; I _{OL} = 16 mA)	V_{OL} = max. 0,4 V
high level	voltage ($V_{CC} = 4,5 \text{ V}; I_{OH} = -0.8 \text{ mA}$)	V _{OH} = min. 2,4 V
short circ	uit current (1 s max; V _{CC} = 5,5 V)	$I_{OS} = max55 mA$
rise time*	(0,5 V to 2,4 V)	max. 15 ns
fall time*	(2,4 to 0,5 V)	max. 15 ns
symmetry	* (1,4 V; 25 °C)	better than 40/60

^{*} At 16 mA sink, 0,4 mA source current, 20 pF load capacitance

Start-up time

typ. 5 ms; max. 50 ms

Temperature range operating

storage

0 to + 70 °C -55 to + 125 °C

AVAILABLE TYPES

Catalogue numbers of 12 digits are fixed per contract, but the following preferred types have been fixed.

1,0	MHz: 4322	199 0011	11	4,0	MHz: 4322	199 00161	i
1,5	MHz: 4322	199 0012	21	4,9152	MHz: 4322	199 00171	l
2,0	MHz: 4322	199 0013	31	6,0	MHz: 4322	199 00181	l
3,0	MHz: 4322	199 0014	11	8,0	MHz: 4322	199 00191	
3,6864	MHz: 4322	199 0015	51	10,0	MHz: 4322	199 00201	l

Special types

Compact integrated oscillators with smaller frequency- or symmetry tolerances or other special requirements are available upon request.

Please consult your supplier for further information.

TEST AND REQUIREMENTS

Essentially all tests are carried out along the lines of IEC publication 68-2, "Recommended basic climatic and mechanical robustness testing procedure for electronic components". Ageing and visual inspection are according to MIL.

Table 1

IEC 68 test method	test	procedure	requirements	
Aa, Ba	storage	16 h, 125 °C/2 h, -55 °C	no failures	
Db	accelerated damp heat	+ 25 °C to + 55 °C 6 cycles	$\Delta f \le 5 \times 10^{-6}$	
Ea	shock	100 g sawtooth, 6 shocks, 3 directions	$\int \Delta f \leq 5 \times 10^{-6}$	
Ed	free fall	250 mm on wood		
Fc	vibration	frequency 10 - 500 Hz, acceleration 20 g, three directions, 30 min.	no damage $\Delta f \leqslant 5 \times 10^{-6}$	
Na	temperature cycling	1 h,40 °C/1 h, + 85 °C 10 cycles	no damage Δf ≤ 5 x 10 ⁻⁶	
α _c , α _x	sealing	16 h, 700 kPa He	< 1 x 10 ⁻⁸ ncc/s	
Т	soldering	solderability: max. 10 s, 260 °C thermal shock: 3 s, 350 °C	good tinning no damage $\Delta f \leqslant 5 \cdot 10^{-6}$	
Ub	bending of terminations	load 5 N, method 1	no visible damage no leaks	

Table 2

MIL test method	test	method	requirements	
MIL-0-55310/16 MIL-Std-883	ageing visual inspection	30 days, 70 °C continuous 2017.1	$\Delta f \le 1.5 \times 10^{-6}$ by agreement with customer	

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